

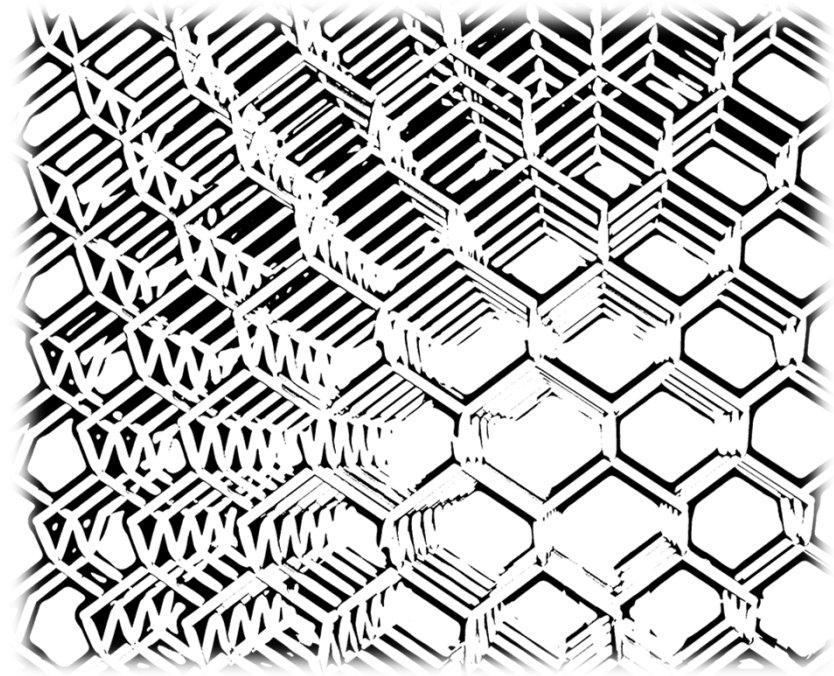
30.5.2018

Diamond Detectors - Status and Perspectives

Alexander Oh
University of Manchester

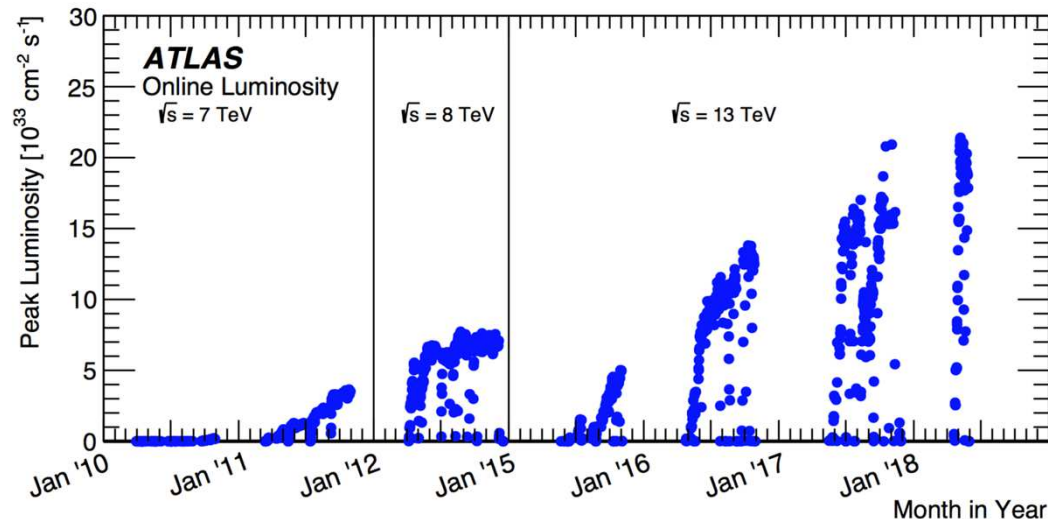
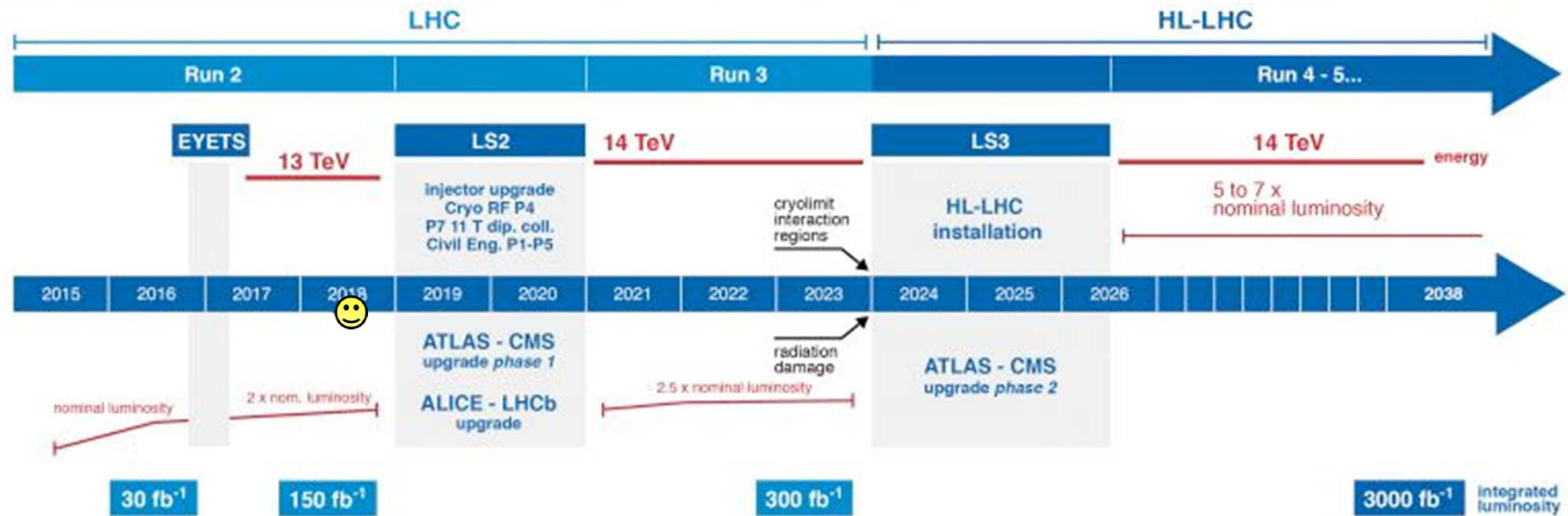
Outline

- Diamond Detectors
- Installations in experiments
- Radiation Hardness
- 3D Diamond detectors



Thanks for the material from the RD42 and ADAMAS collaborations!

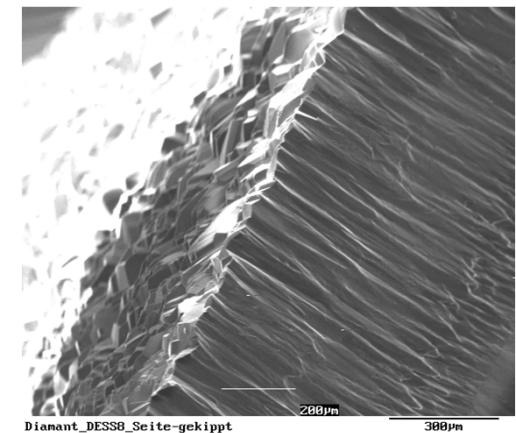
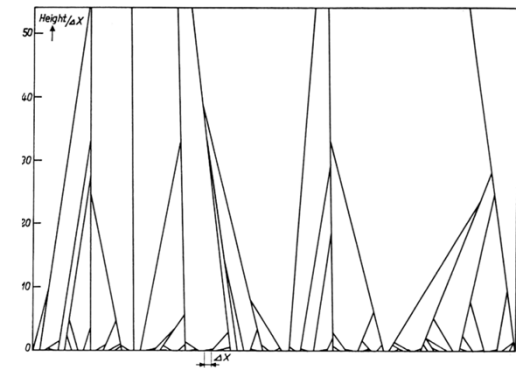
Challenges Ahead



- Luminosity upgrades of the LHC will increase the luminosity by factor ~ 3 .
- Luminosity \sim Radiation damage.
- Need new technologies in the innermost layers to survive the radiation levels.

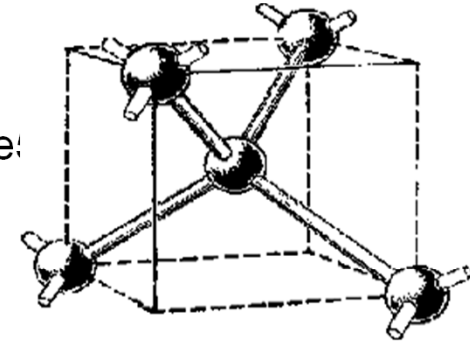
Diamond

- 1941 – Diamond as particle detector (Stetter)
- 1953- CVD process, synthesis of diamond (Eversole)
- ~1980 – polycrystalline CVD diamond.
- 1995 – first diamond strip detector
- 1996 – first diamond pixel detector
- 2011 – first 3D diamond detector



Diamond properties

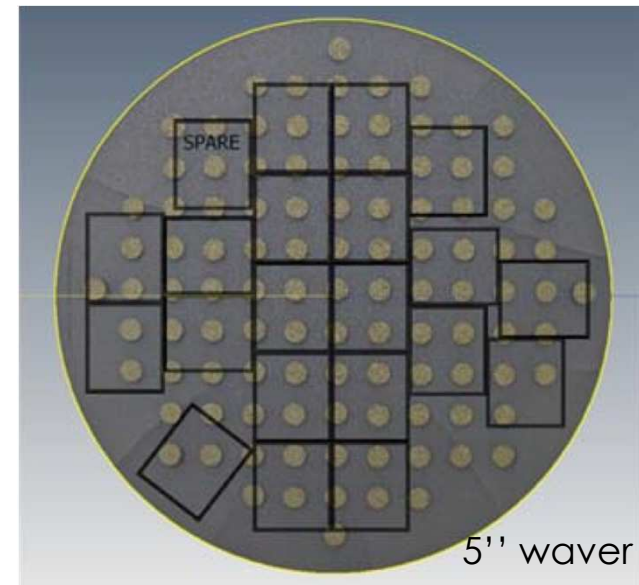
Property	Diamond	Silicon
band gap	5.47	1.12
mass density [g/cm ³]	3.5	2.33
dielectric constant	5.7	11.9
resistivity [Ω cm]	>10 ¹¹	2.3e ⁴
breakdown [kV/cm]	1e3...20e3	300
e mobility [cm ² /Vs]	2150	1350
h mobility [cm ² /Vs]	1700	480
therm. conductivity [W / cm K]	10..20	1.5
radiation length [cm]	12	9.4
Energy to create an eh-pair [eV]	13	3.6
ionisation density MIP [eh/mm]	36	89
ion. dens. of a MIP [eh/ 0.1 ‰ X ₀]	450	840



- Low dielectric constant → low capacitance
- Low leakage current → low noise
- Room temperature operation
- Fast signal collection time
- MIP signal ~2 smaller at same X₀
- Efficiency < 100% (pCVD)

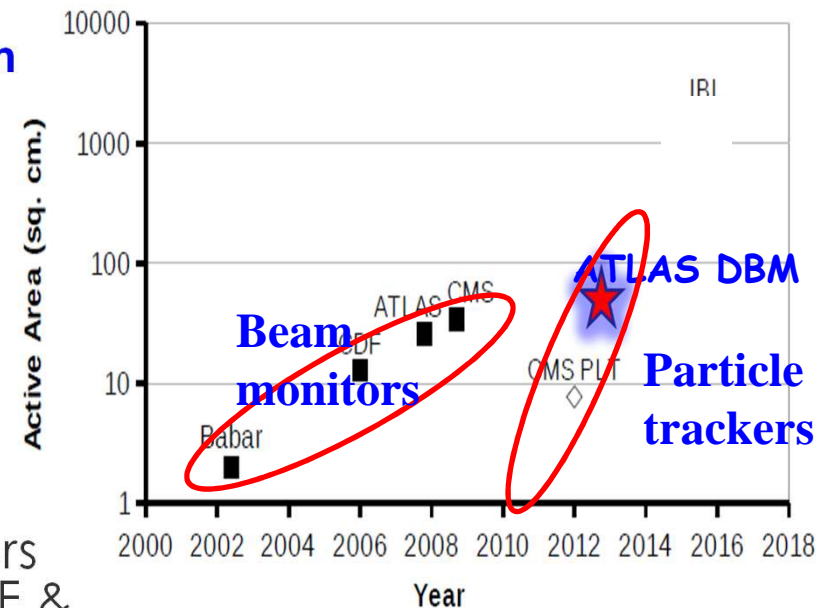
Development of CVD Diamond for detector applications

- Today two main manufacturers of detector grade diamond
 - **ElementSix Ltd**
 - large **polycrystalline** wafers
 - **single crystal** diamonds
 - **II-VI Semiconductors**
 - large **polycrystalline** wafers
 - relatively recent entry
- Alternative sources
 - Diamond on Iridium (DoI) (Audiatec, Germany)
 - Hetero-epitaxially grown -> **large area**
 - **Highly oriented crystallites.**



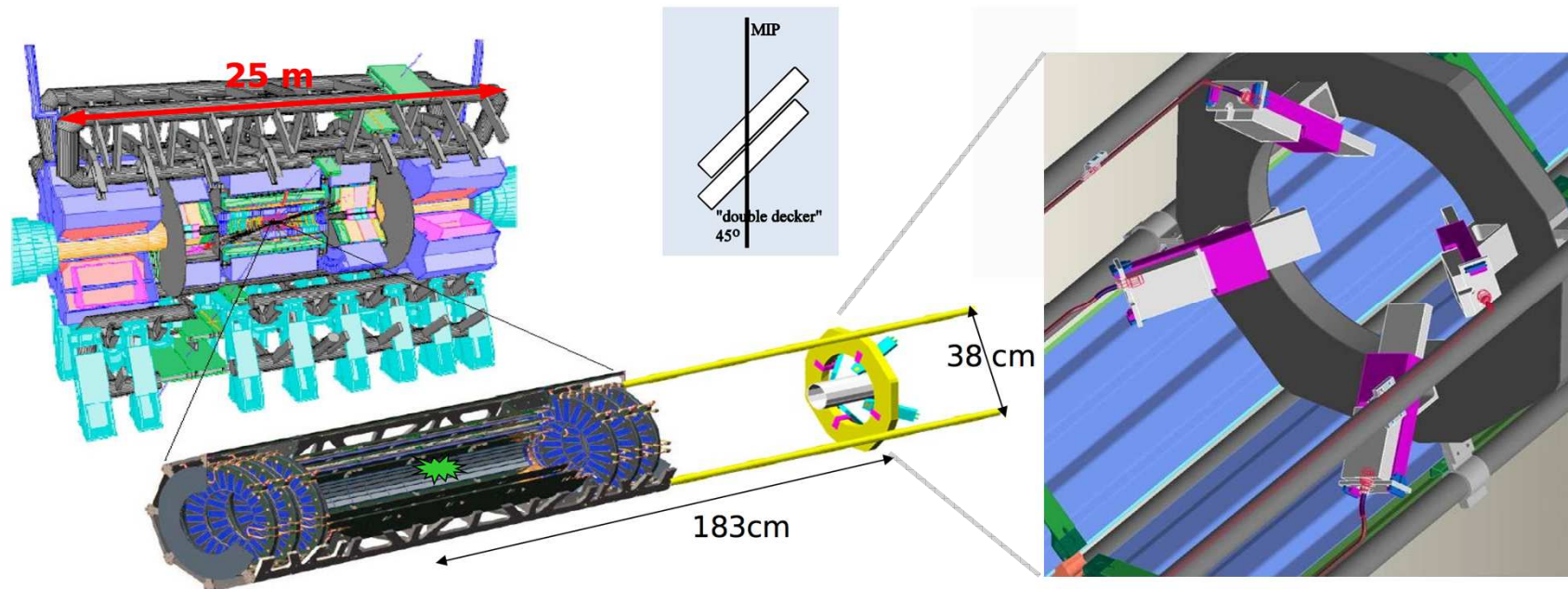
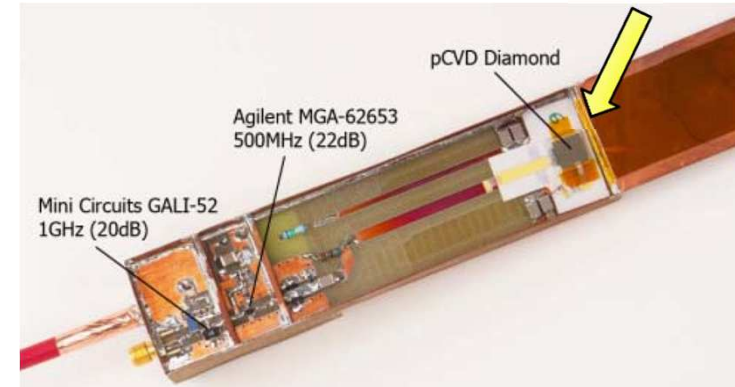
Diamond in current HEP experiments

- **Beam monitors** to protect experiments against **beam losses** at the LHC, CERN.
 - For Silicon Vertex systems careful monitoring is crucial.
 - Beam monitors have to be **radiation hard**.
 - Abort beam when monitors signal dangerous beam conditions.
 - False signals must be avoided.
- During run-1 **diamond beam monitors operated** in ATLAS, CMS, and LHCb.
- Previously diamond beam monitors were installed in BaBar(SLAC), CDF & D0 (Tevatron).



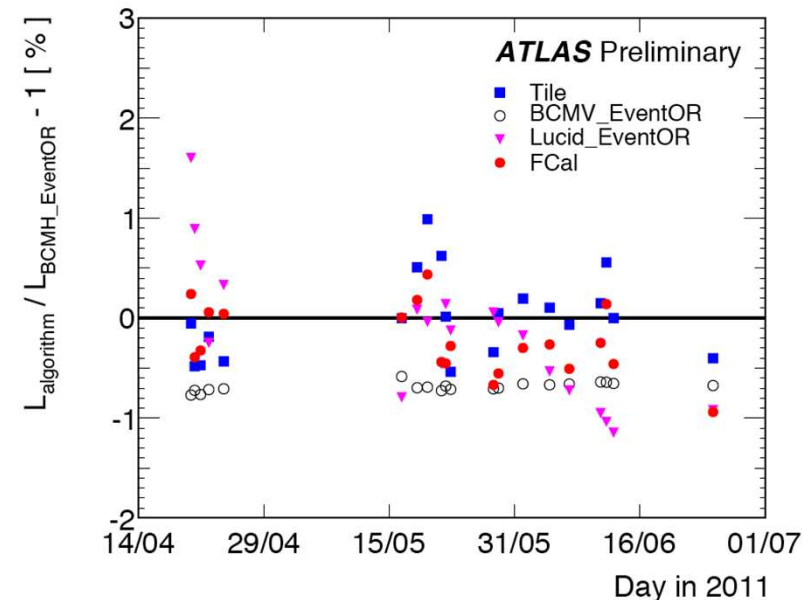
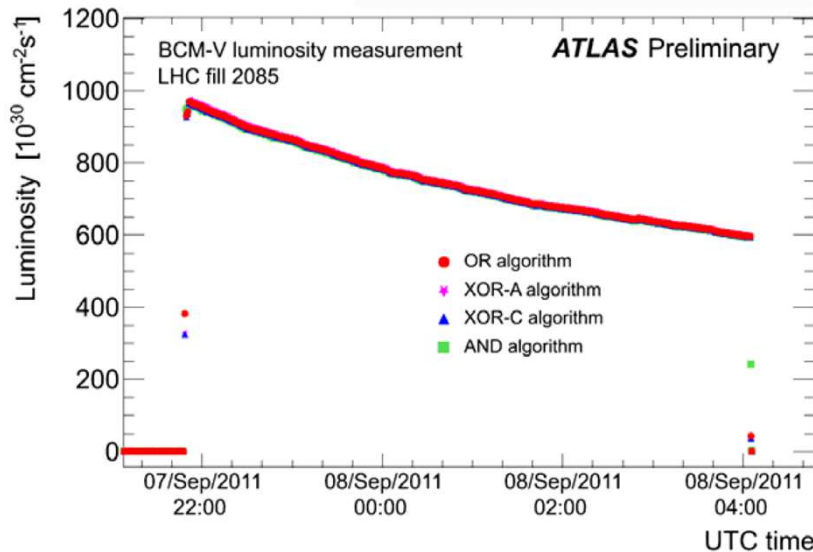
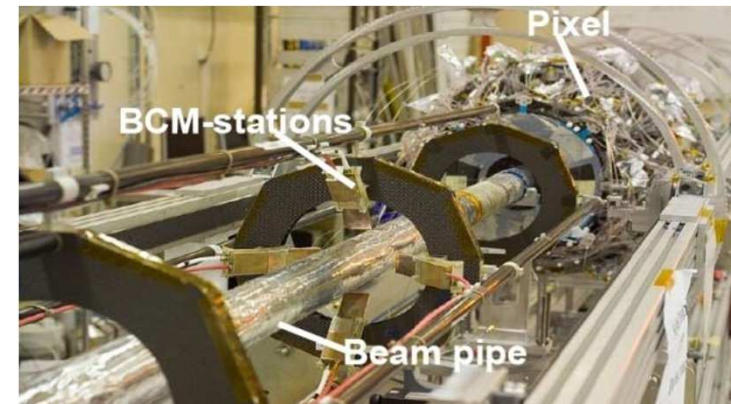
ATLAS beam conditions monitor

- Use 2x polycrystalline CVD diamonds per station (10 x 10 mm).
- 4 stations on each side of the ATLAS pixel detector
 - $z = \pm 183.8 \text{ cm}$ ($\sim 12.5 \text{ ns}$) and $r \sim 5 \text{ cm}$



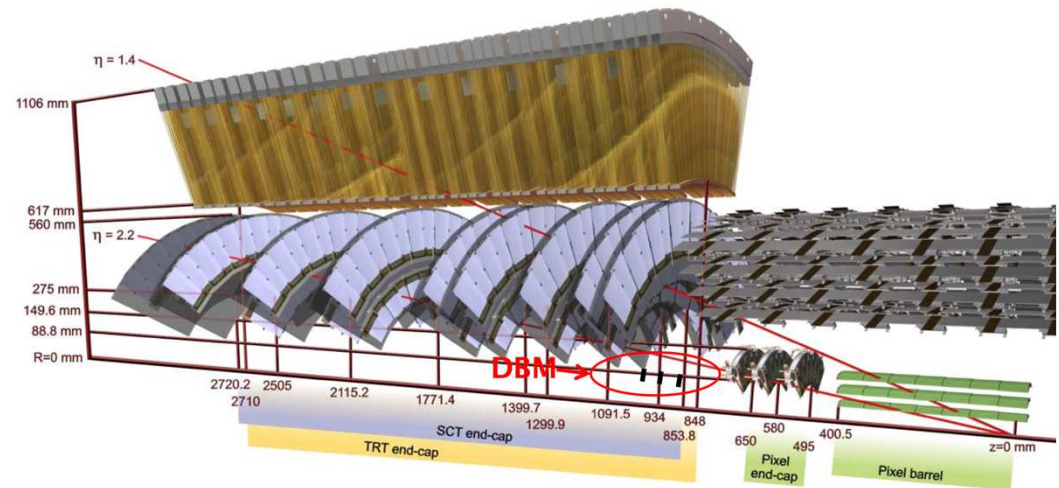
ATLAS beam conditions monitor

- Single particle counting with $\sigma=0.7\text{ns}$.
- Distinguish between collision events and out-of-time background.
- Good stability in run-1
- Used for luminosity determination.



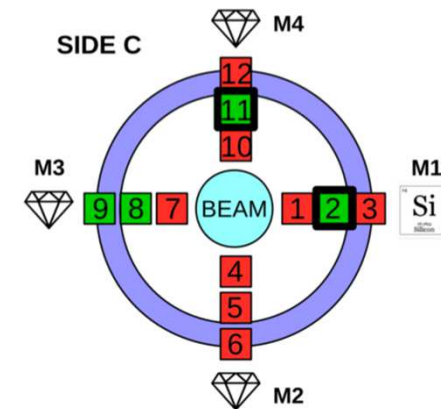
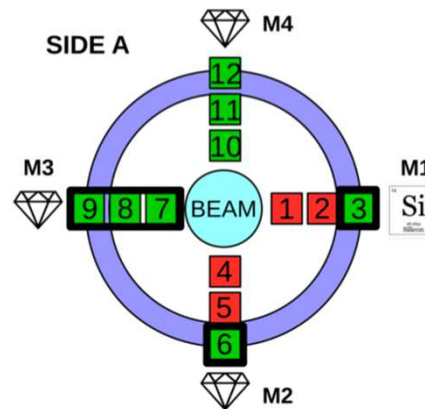
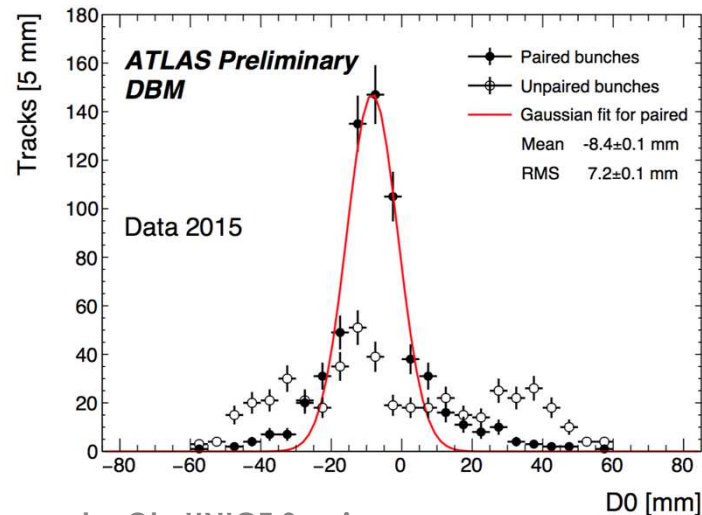
Run 2: ATLAS Diamond Beam Monitor

- 8 mini-trackers of 3 planes each using pixel-detectors.
- polycrystalline diamond sensors, 18mm x 21mm, $\delta > 250\mu\text{m}$.
- bump-bonded to FE-I4 pixel read-out chip.
 - 336 x 80 pixels
 - pixel size : 50 μm x 250 μm
- Purpose:
 - Bunch-by-bunch luminosity monitor (aim < 1 % per BC per LB)
 - Bunch-by-bunch beam spot monitor



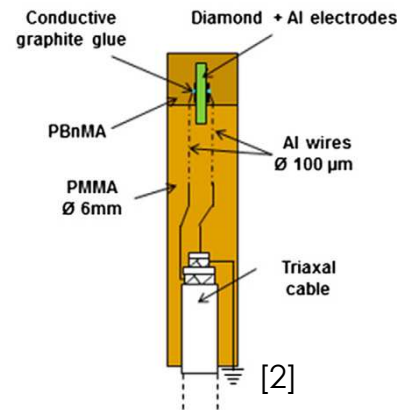
Run 2: ATLAS Diamond Beam Monitor

- Installed in ATLAS during LS1, but switched off due to unexpected death of Si and Diamond modules.
- DBM recommissioned in 2017/18 with 50% working modules.

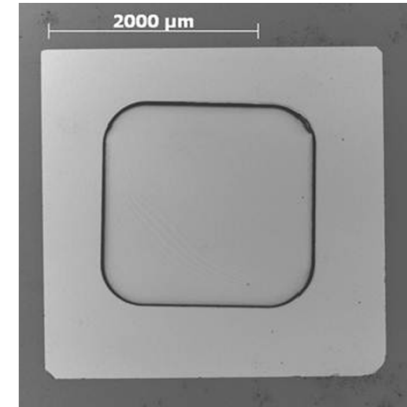


Examples of diamond detectors in related areas

- Synchrotron labs
 - beam position monitor
- Radiation Therapy
 - small field dosimetry
- Heavy Ion (GSI, FAIR)
 - beam diagnostic
 - particle tracking and TOF
 - hadron spectroscopy



scCVD dosimeter,
0,4 mm³ active vol. [2]



3 μm thick membrane
in 40 μm thick scCVD [1]

[1] M. Pomroski, CEA-LIST, MRS Fall meeting, Boston 28/11/2012

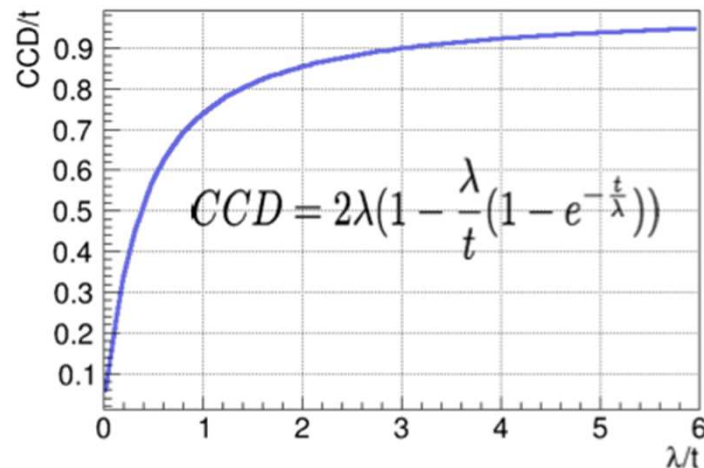
[2] F. Marsolat et al. / Diamond & Related Materials 33 (2013) 63-70

Radiation Hardness

- **Irradiated polycrystalline and single crystal CVD diamond.**
 - Protons 25MeV, 70MeV, 300MeV, 800MeV, 24GeV
 - Pions 300MeV
- **Signal response tested in test-beam.**
 - 120 GeV proton
 - strip-detector pattern, $E = \pm 2V/\mu\text{m}$
 - Samples pre-exposed to Sr90 to fill traps (aka *pumping*)
 - Require track on active area, no threshold on strip signals.
 - Build signal of two highest signals within 10 strips around the track.

Radiation Hardness

- “Charge Collection Distance” (CCD) is measured.
- Traps reduce the life-time of charge carriers, or “Schubweg” (λ).
 - Relation between CCD and λ :



Radiation damage is fitted with simple damage model:

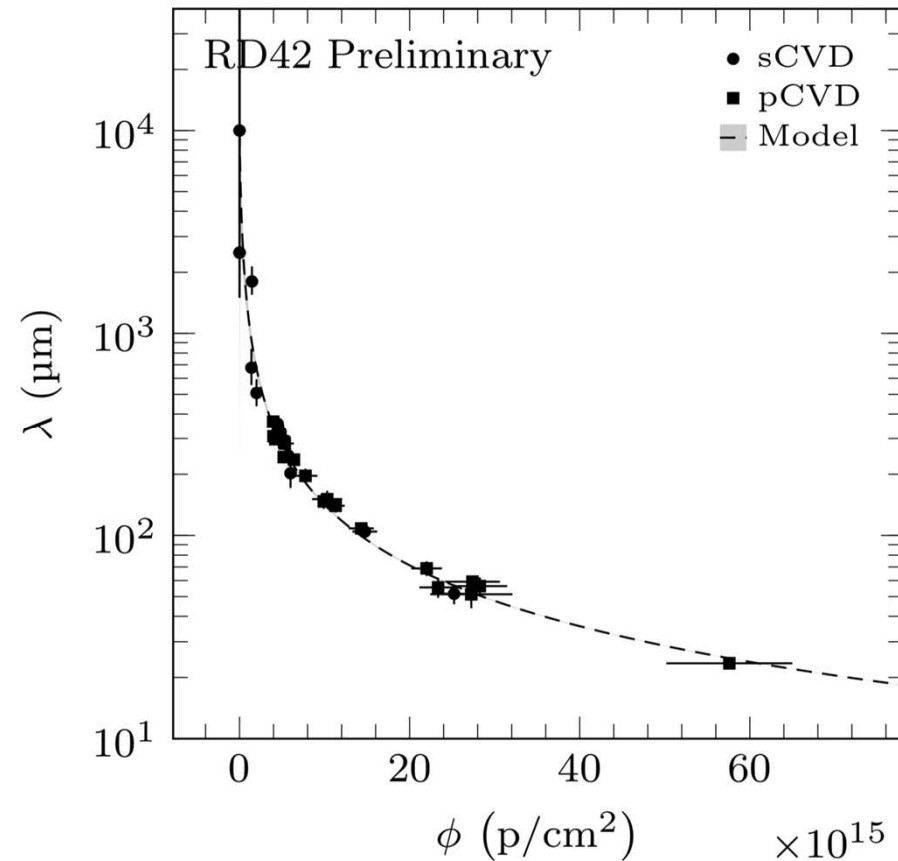
$$\frac{1}{\lambda} = \frac{1}{\lambda_0} + k_{\lambda} \Phi$$

damage constant
particle flux

Radiation Hardness

■ 24 GeV protons

- $k_\lambda = 0.67 \pm 0.04 \times 10^{-18}$
 $\text{cm}^2\mu\text{m}^{-1}$
- polycrystalline diamond
sample offset by
 $\Phi \sim 5 \times 10^{15}$ to account for
existing traps.
- Poly and single crystal
diamond show consistent
damage constants.



<https://www.research-collection.ethz.ch/handle/20.500.11850/222412>

Radiation Hardness

- Summary of RD42 irradiation results:

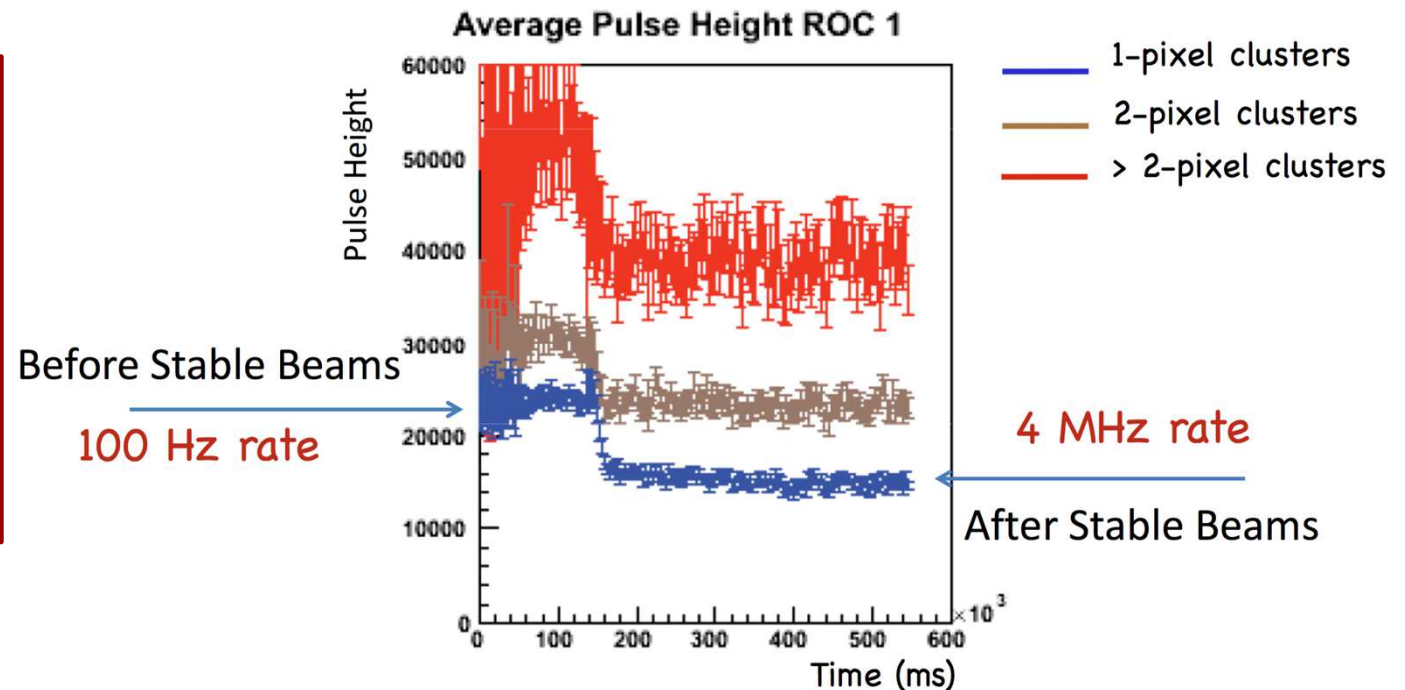
Particle Species	Relative Damage Constant, κ
24 GeV p	1
800 MeV p	1.85 ± 0.13
70 MeV p	2.5 ± 0.4
25 MeV p	4.5 ± 0.6
fast neutrons	4.5 ± 0.5
200 MeV π	2.5 - 3

*normalized to 24GeV protons

High Rate tests

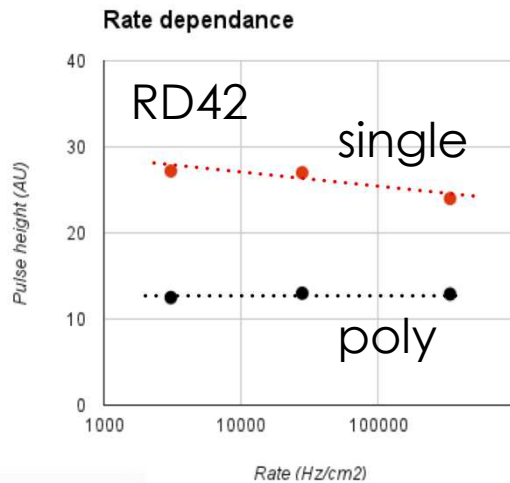
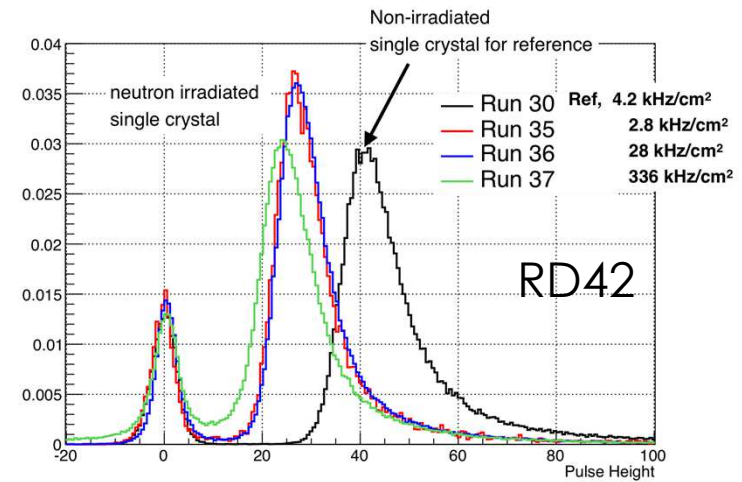
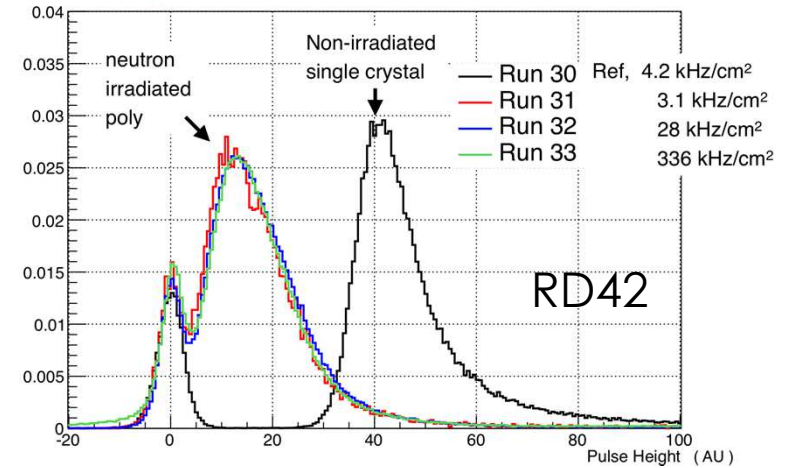
- Tests the pulse height as function of particle rate.
- Test single and poly crystalline diamond.
- Irradiated and un-irradiated.

Investigations triggered by indication of rate dependence of of single crystal diamond pixel detector installed in CMS in 2012.

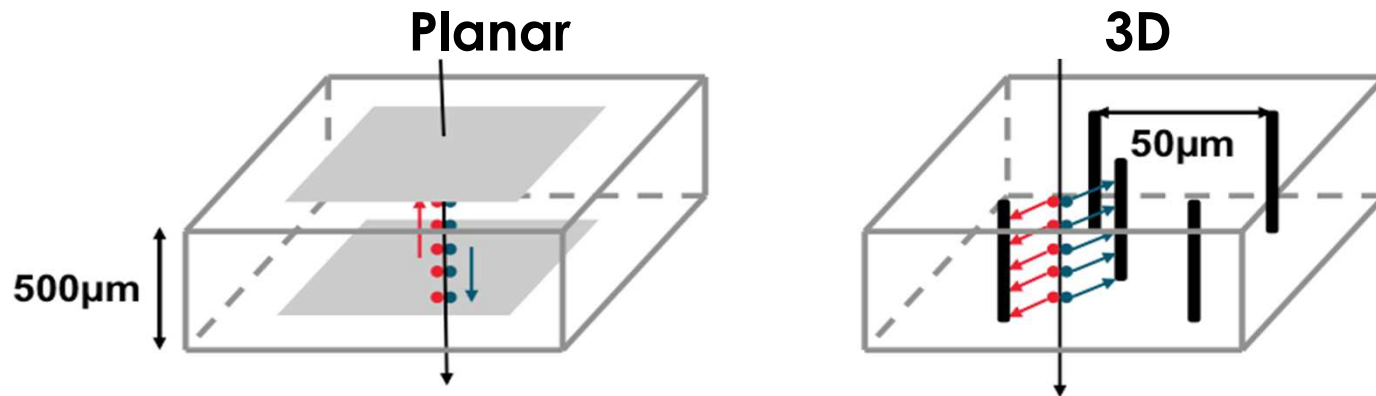


High Rate tests

- single and poly sample irradiated with 5×10^{13} reactor n.
- Tested with 250MeV pions.
- Slight rate dependence observed in irradiated **single crystal** sample.
- No rate dependence observed for irradiated **polycrystalline** sample.



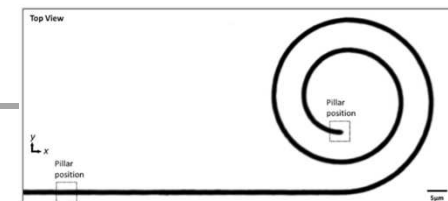
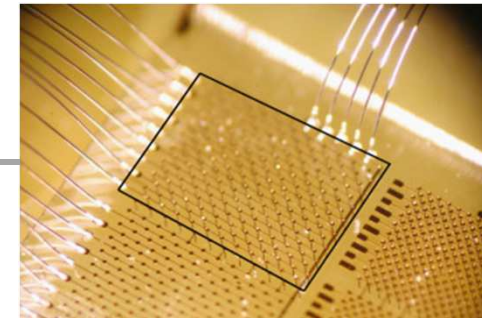
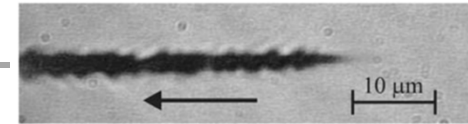
3D Diamond Detectors



- Electrode spacing determines drift distance to induce 1e charge.
- 3D has shorter electrode spacing compared to planar.
- Charge carriers need less drift distance (and time) in 3D than in planar to induce equal signal.
- Influence of traps and resulting limited lifetime suppressed in 3D.

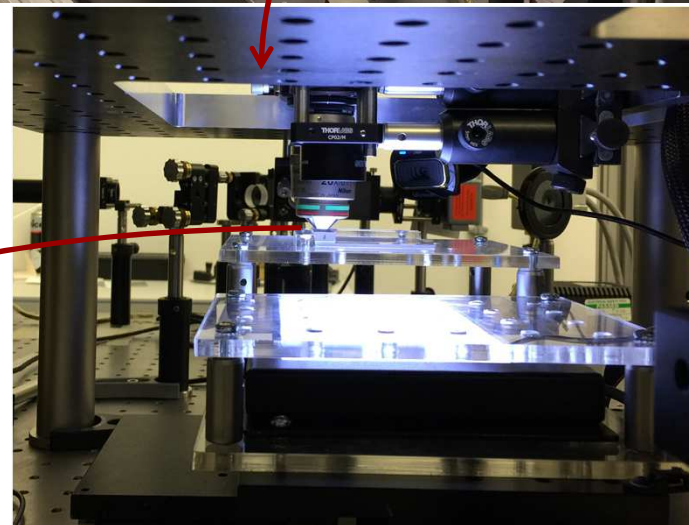
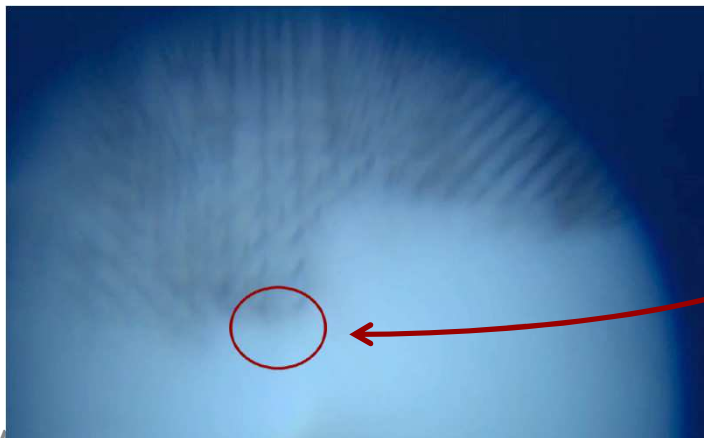
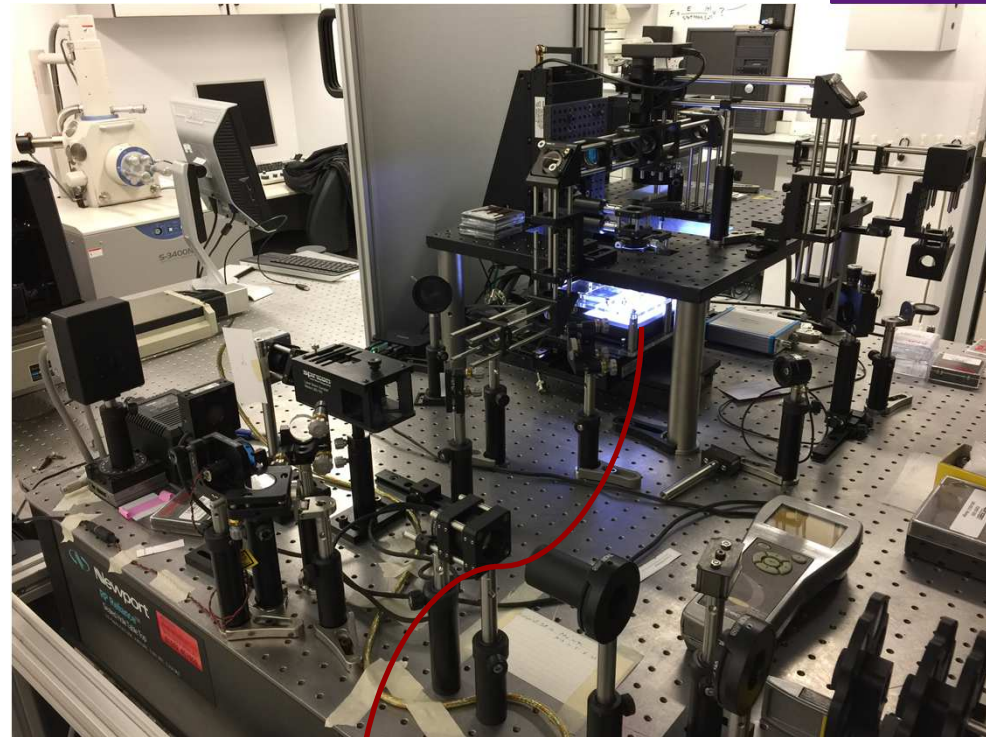
3D Diamond Research - A relatively young field

- Laser induced phase change in diamond.
 - E.g. T.V. Kononenko et al, Diamond & Related Materials 18 (2009) 196–199
“Femtosecond laser microstructuring in the bulk of diamond “
- 3D “Pad” detector
 - E.g. S. Lagomarsino et al, Appl. Phys. Lett. 103, 233507 (2013), *“Three-dimensional diamond detectors: Charge collection efficiency of graphitic electrodes”*
- 3D “strip array” detector with position resolution.
 - E.g. F. Bachmaier et al, NIM A, 786, (2015) 97-104,
“A 3D diamond detector for particle tracking”
- Radiation damage studies.
 - Eg. S. Lagomarsino et al, Applied Physics Letters 106, 193509 (2015)
“Radiation hardness of three-dimensional polycrystalline diamond detectors”
- Improvements in graphitization process.
 - Eg. B. Sun et al., Applied Physics Letters 105, 231105 (2014), *“High conductivity micro-wires in diamond following arbitrary paths”*



**University of Manchester, Laser
Processing Research Center.**

- Wavelength = 800 nm
- Repetition rate = 1 kHz
- Pulse duration = 100 fs
- Spot size = 10 μ m
- Pulse Energy ~ 1 μ J
- **Spatial light modulator**

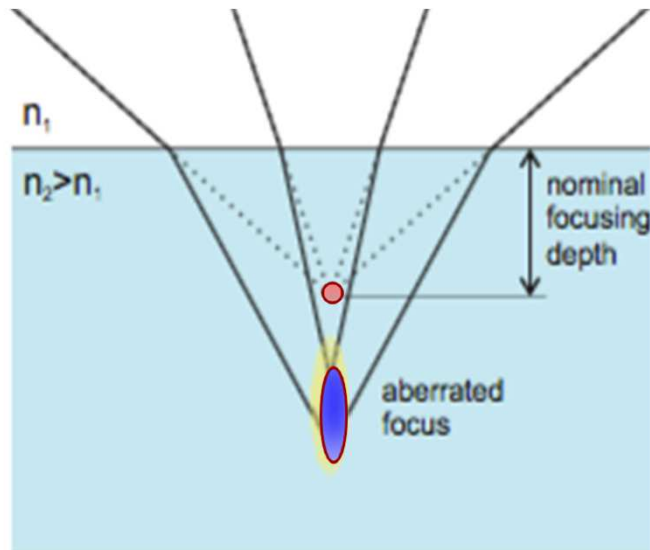
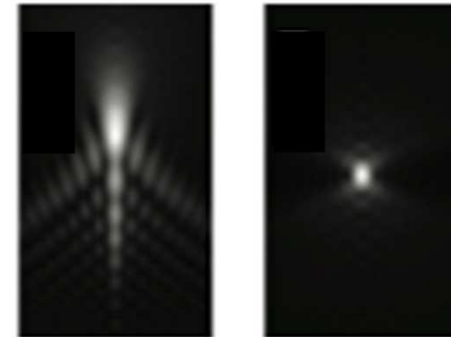
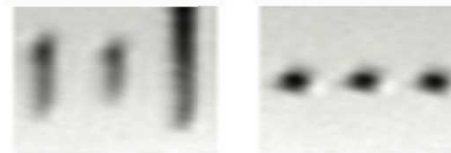
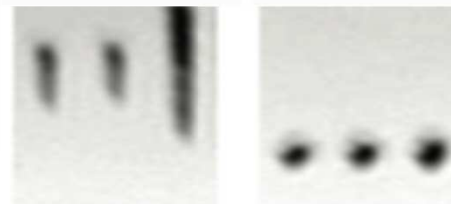


SLM – Phase **S**patial **L**ight **M**odulation

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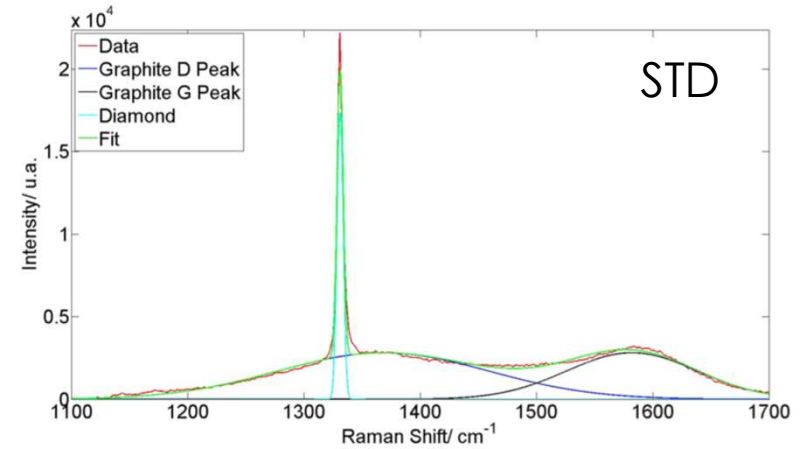
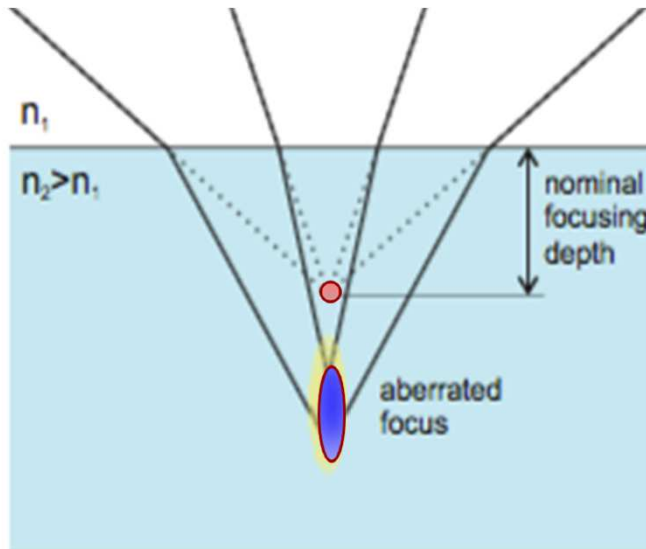
- Comparison SLM vs standard process.

	Std.	SLM
Resistivity	1 Ω cm	0.1 Ω cm
Diameter	$\sim 3\mu\text{m}$	$\sim 1\mu\text{m}$
Diamond to graphite ratio	~ 4	~ 0.2

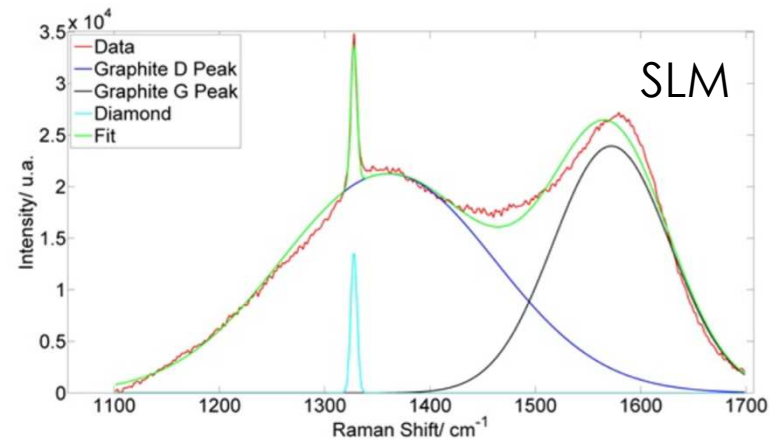
Simulated
depth = $40\mu\text{m}$ Measured
depth = $40\mu\text{m}$ depth = $80\mu\text{m}$ depth = $130\mu\text{m}$ 

- Comparison SLM vs standard process.

	Std.	SLM
Resistivity	1 Ωcm	0.1 Ωcm
Diameter	$\sim 3\mu\text{m}$	$\sim 1\mu\text{m}$
Diamond to graphite ratio	~ 4	~ 0.2

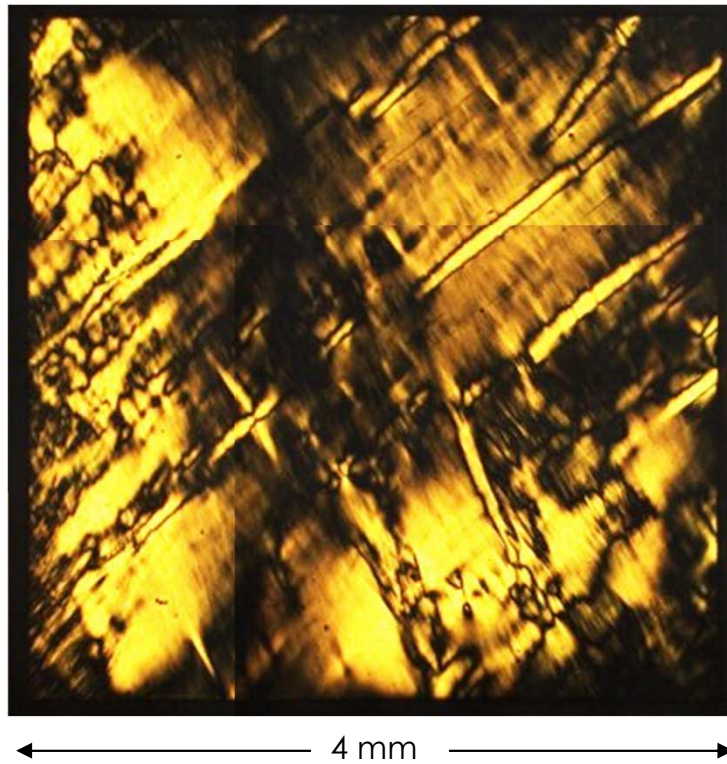


(a)

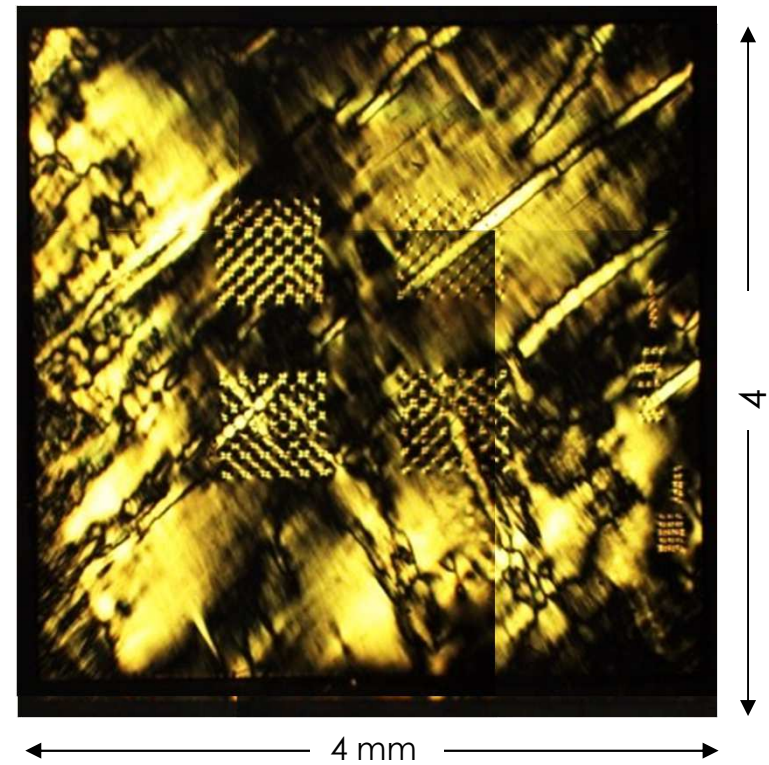


X-polariser image

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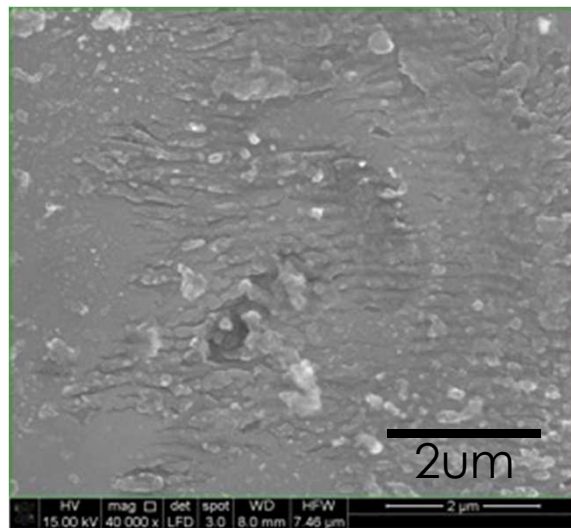
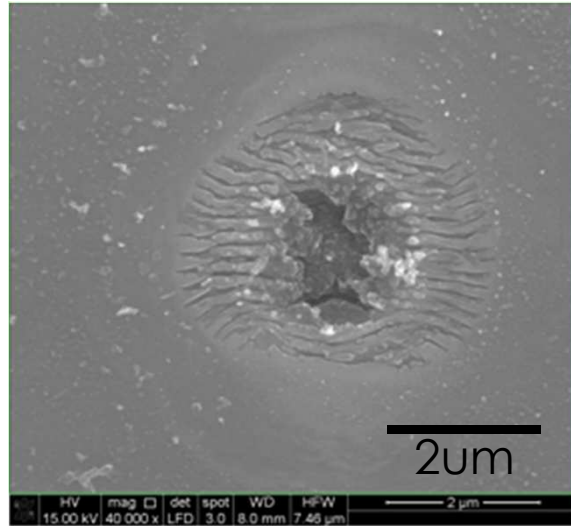
- Optical grade scCVD diamond.



- Post processing.

SEM surface image

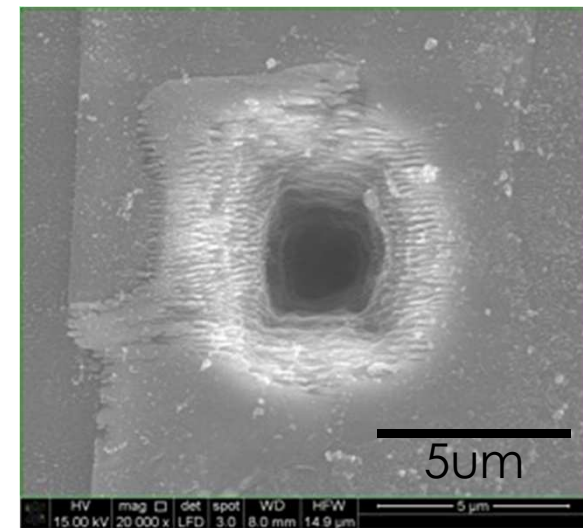
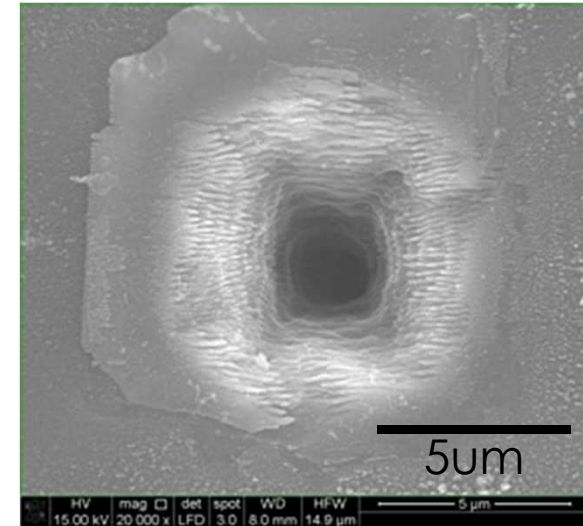
- Seed surface

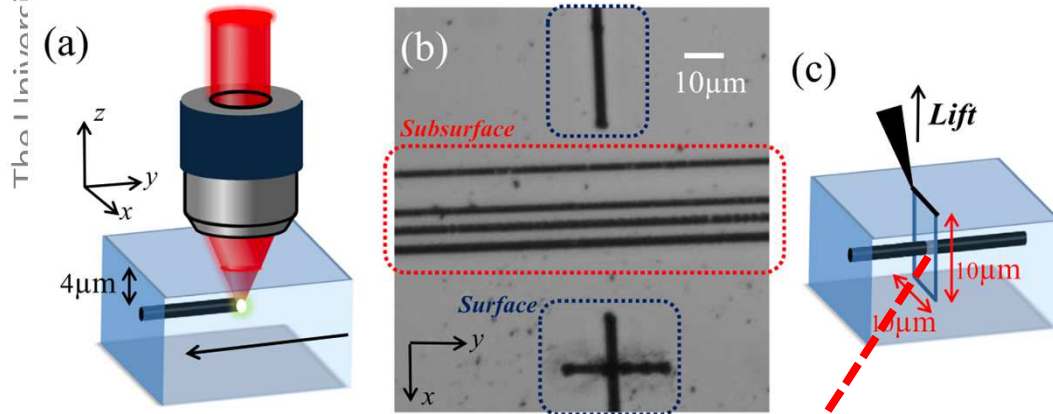


With SLM
10µm/s
400nJ

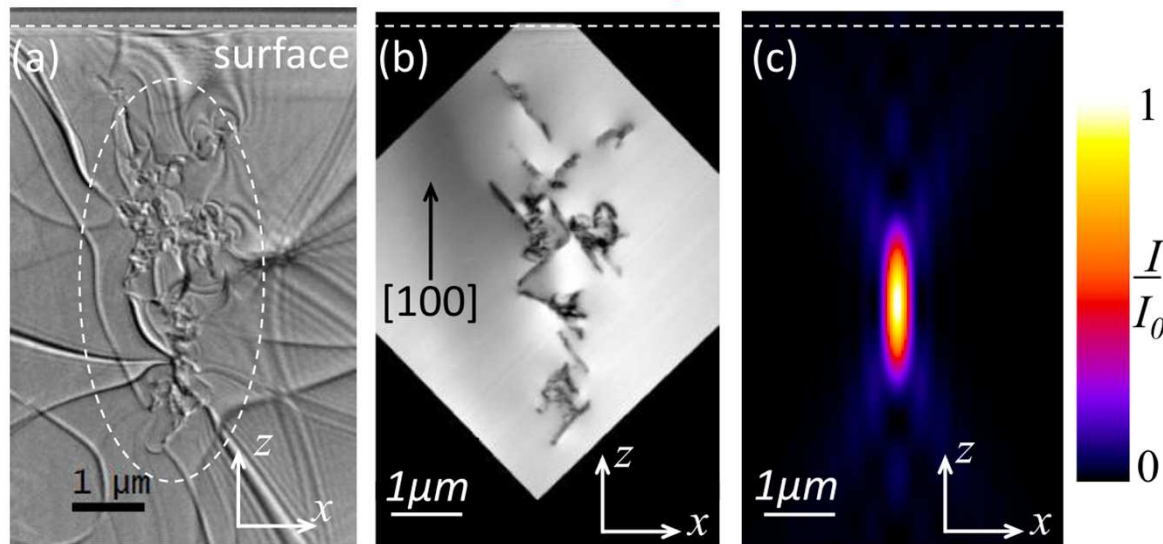
Without SLM
10µm/s
400nJ

- Exit surface





Patrick S. Salter et al.,
APPLIED PHYSICS LETTERS 111,
081103 (2017)



- Prepare sample with horizontal graphitic wires.
- STEM image of wire cross section.
- Optical and spectral data points to micro-cracks and nano-clusters of sp^2 bonded carbon.
- Micro wires are not macroscopic structures!

Parameter space scan

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Patrick Salter, Oxford

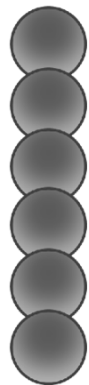
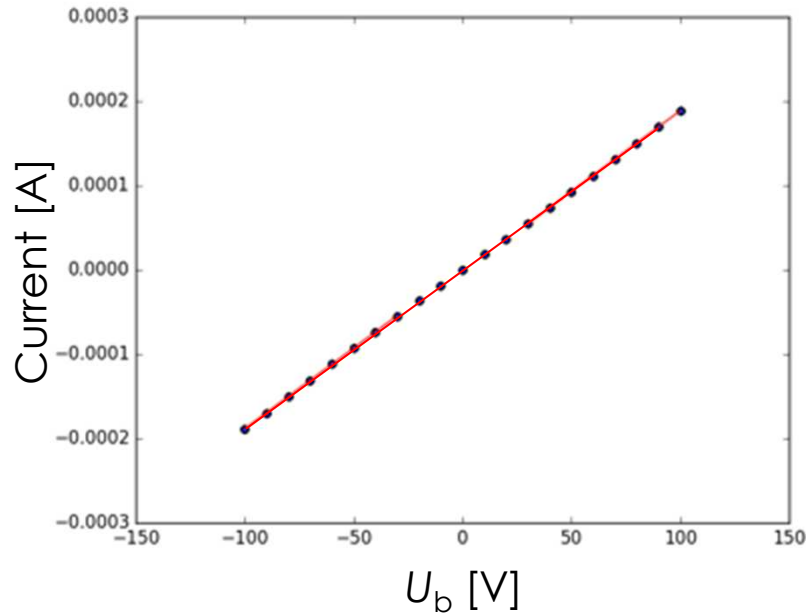
Iain Haughton, AO, Manchester

		Laser translation speed			
		5um/s	10um/s	20um/s	30um/s
Laser beam energy	100nJ	x	x		
	200nJ	x	x	x	
	300nJ		x	x	x
	400nJ		x	x	x
	500nJ			x	x
	600nJ				x

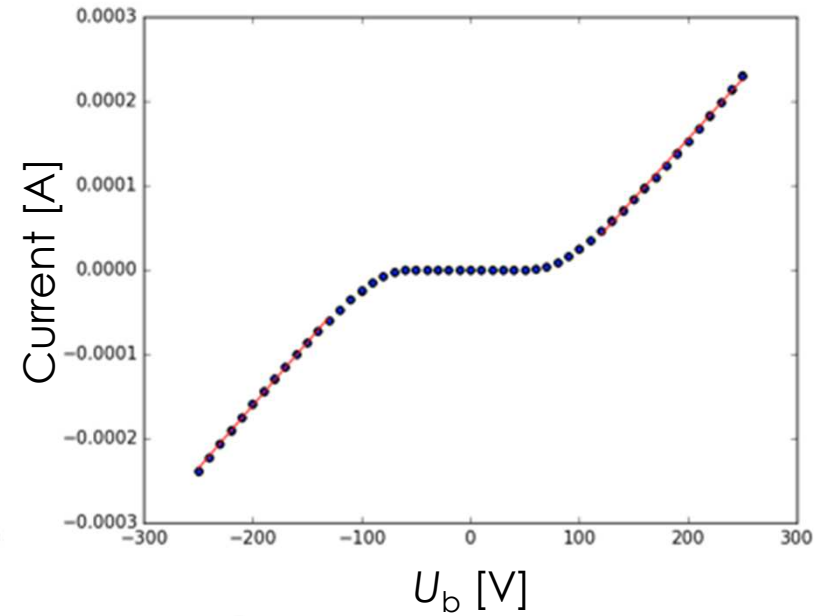
- Repeat **with** and **without** SLM correction.

IV curves

- Ohmic and barrier potential curves observed.

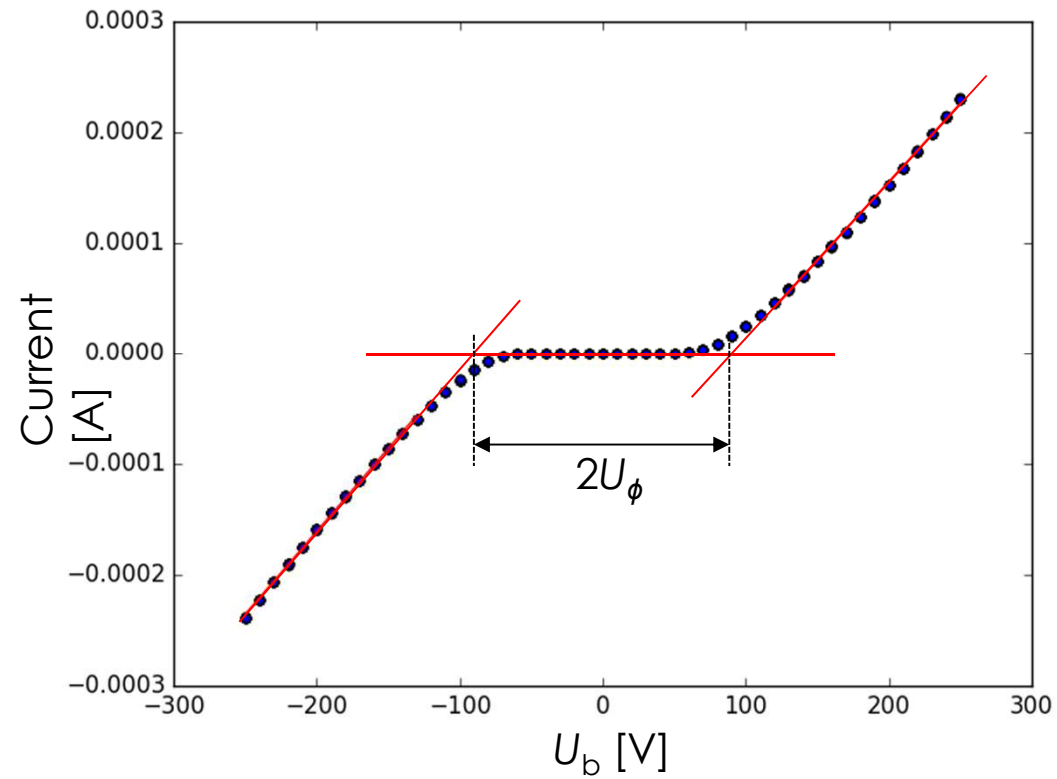


Continuous.



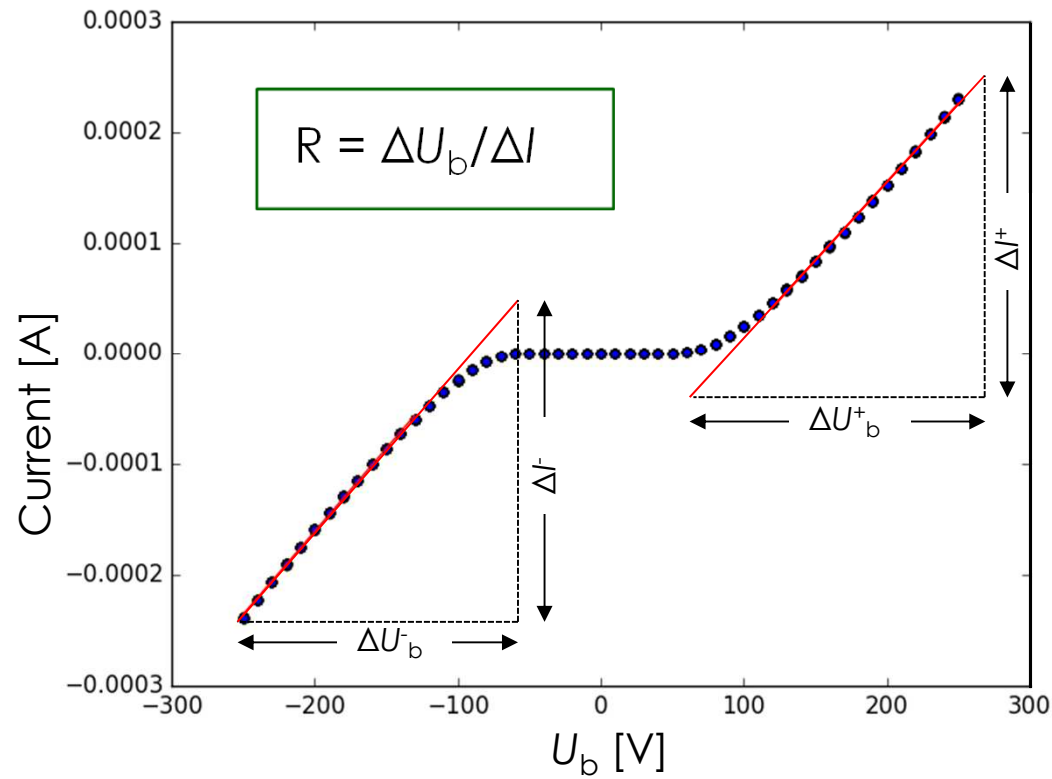
Bulk effect?
Micro gaps?

Barrier potential

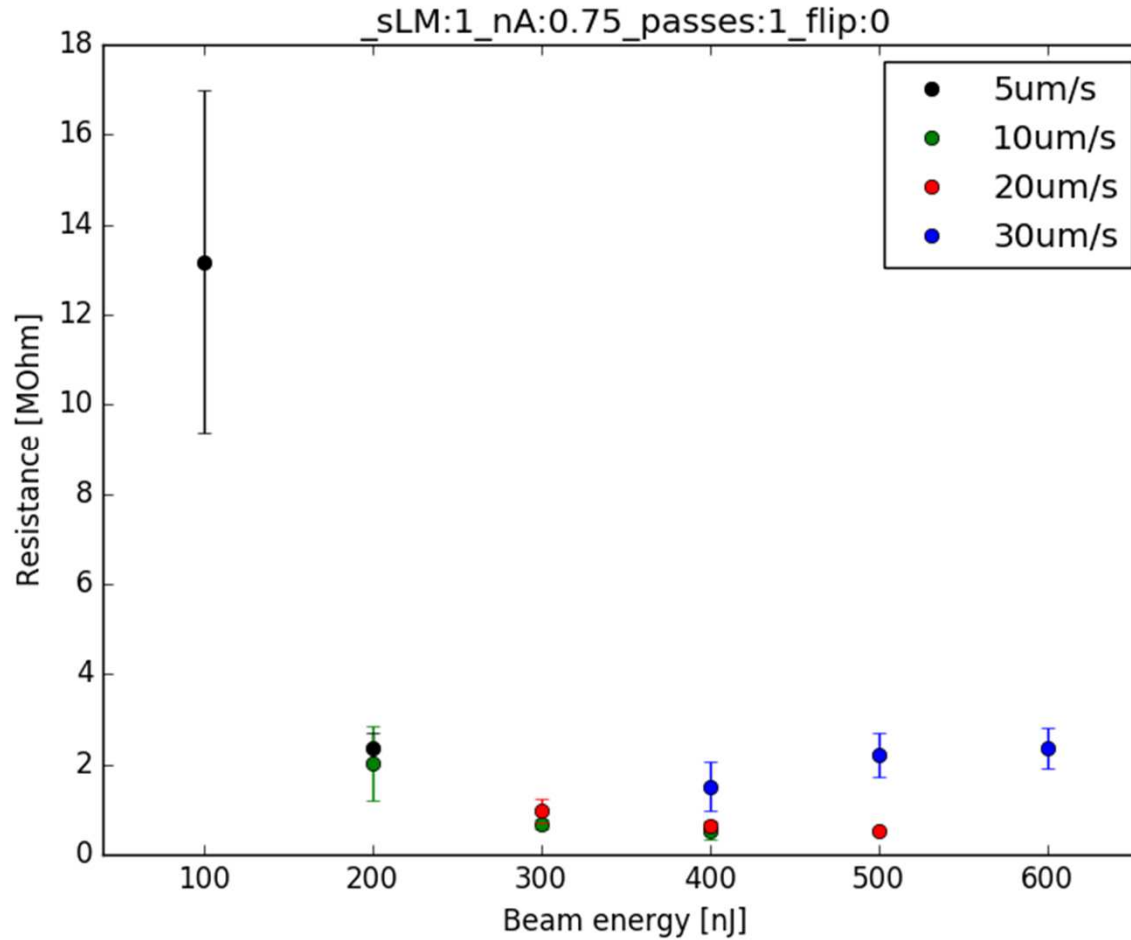


Resistance measurement

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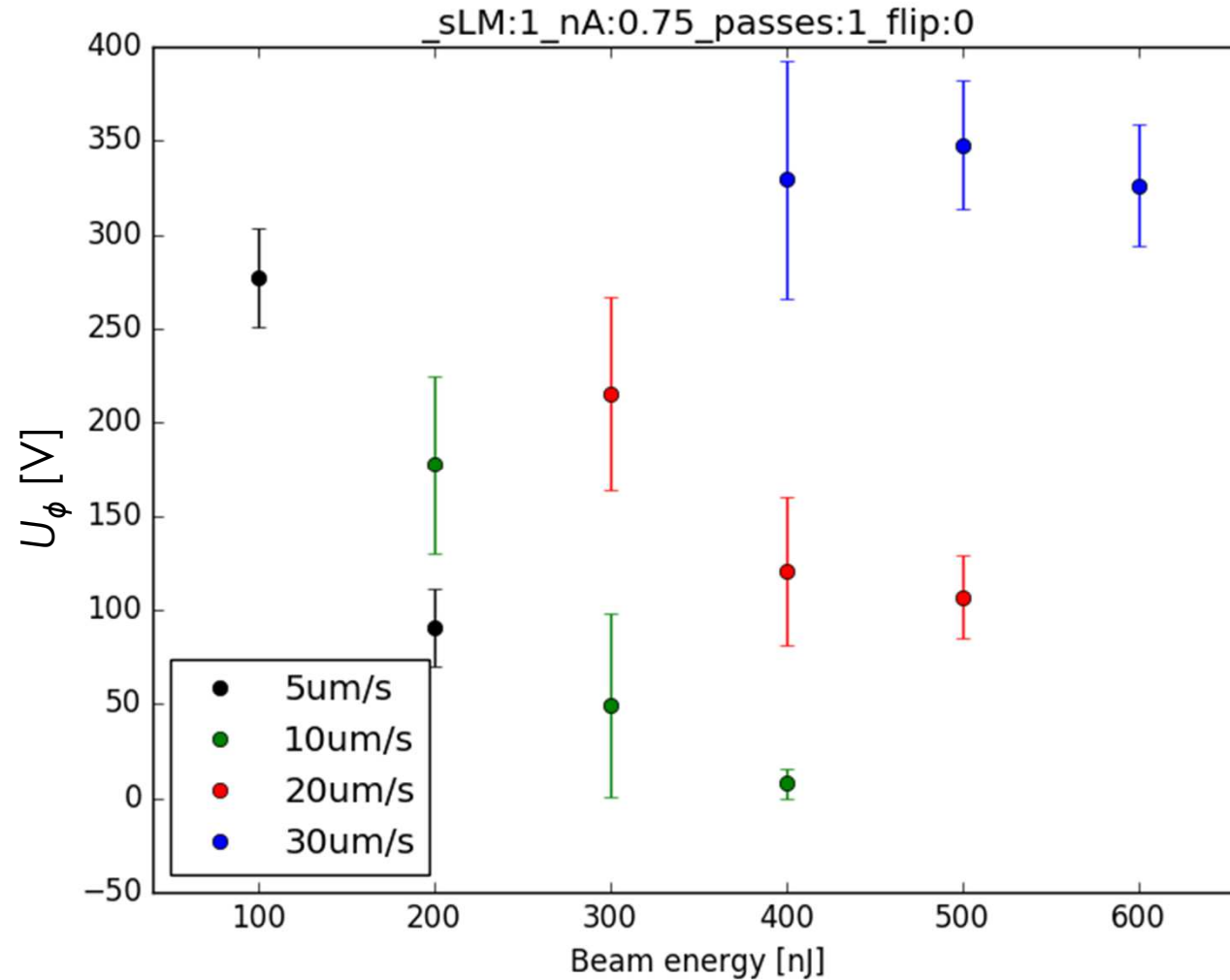
Resistance



- Resistance increase as power law
→ multi-photon process.

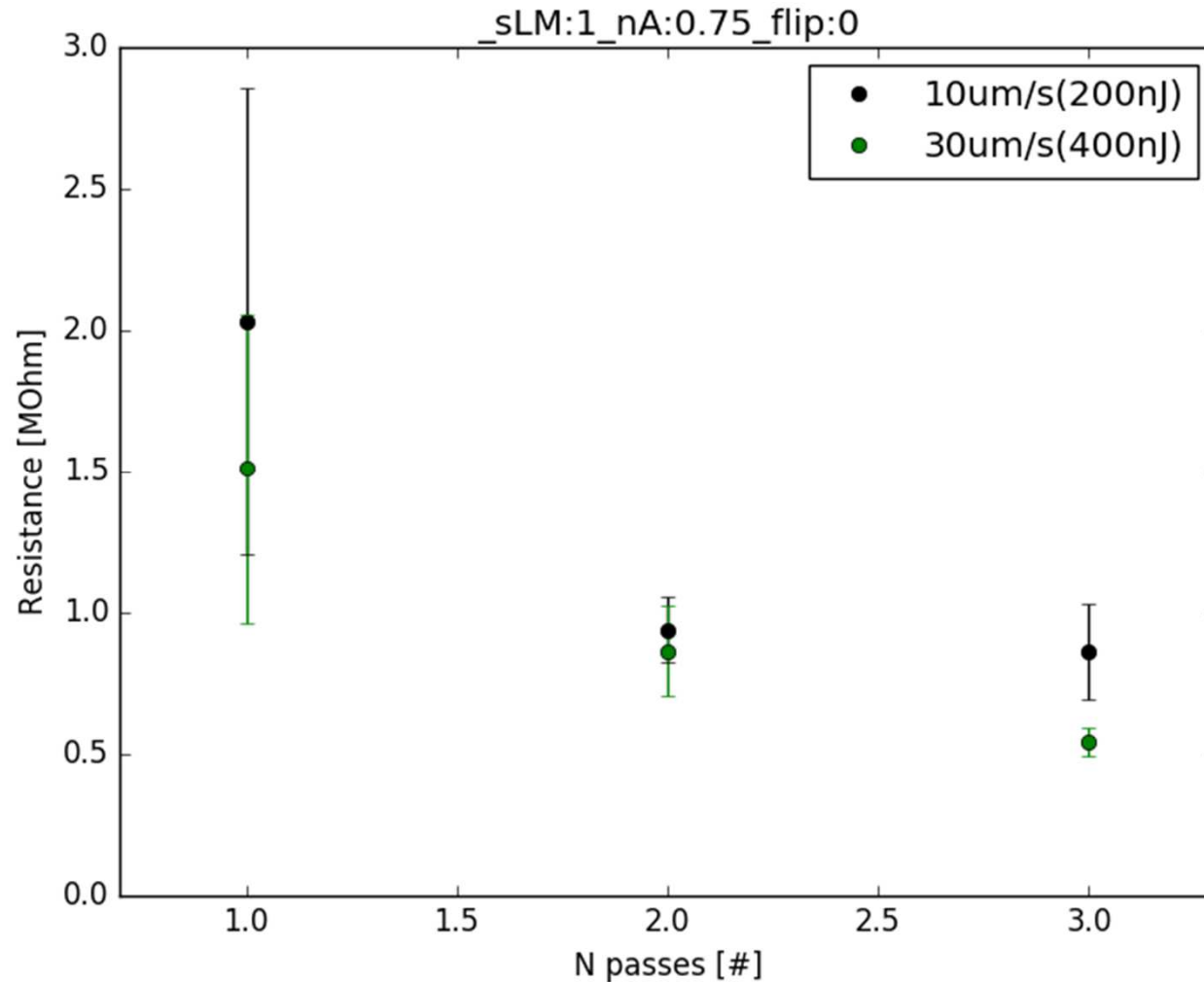
- Clear discrepancy at 30μm/s.

Barrier energy



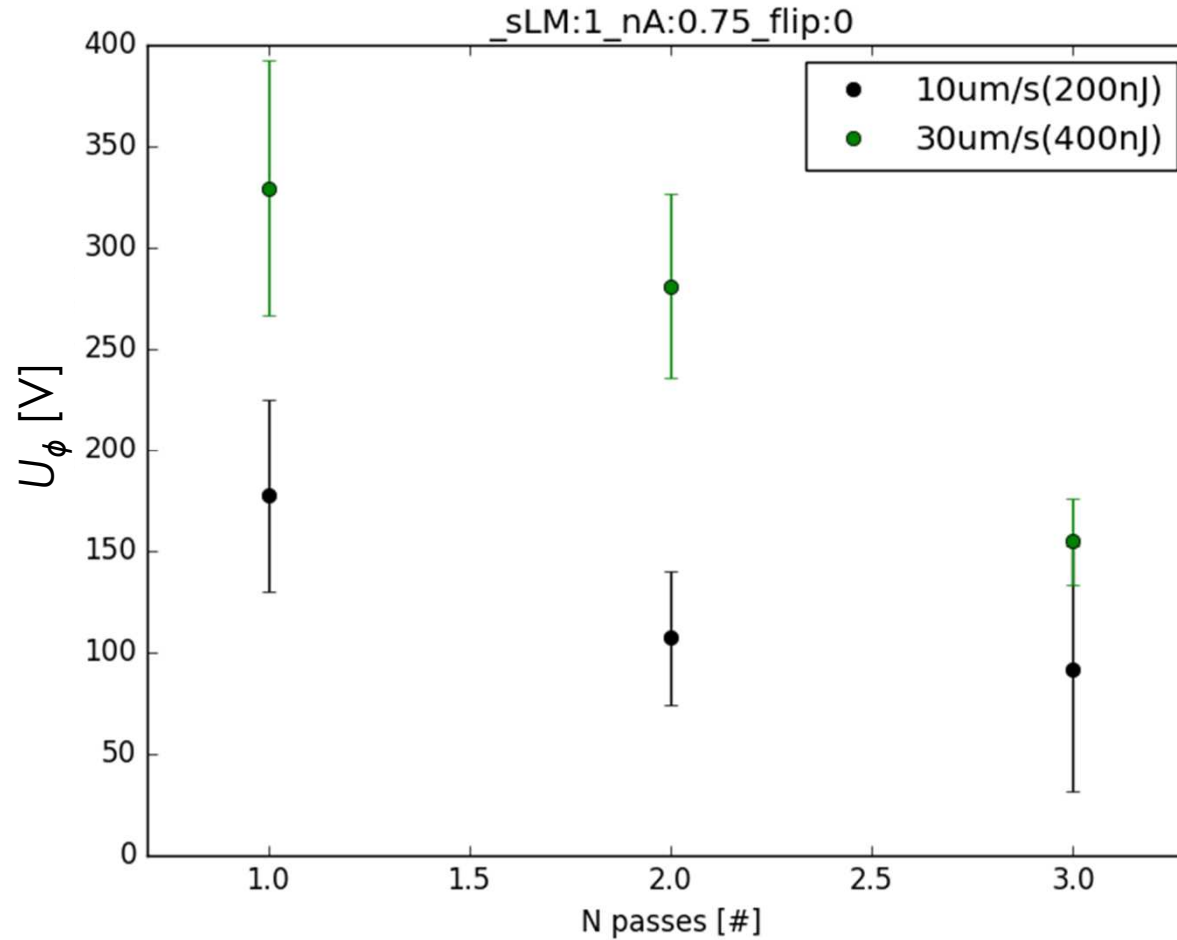
- Reduction in barrier with increased energy.
- Discrepancy at 30um/s.

Multiple passes



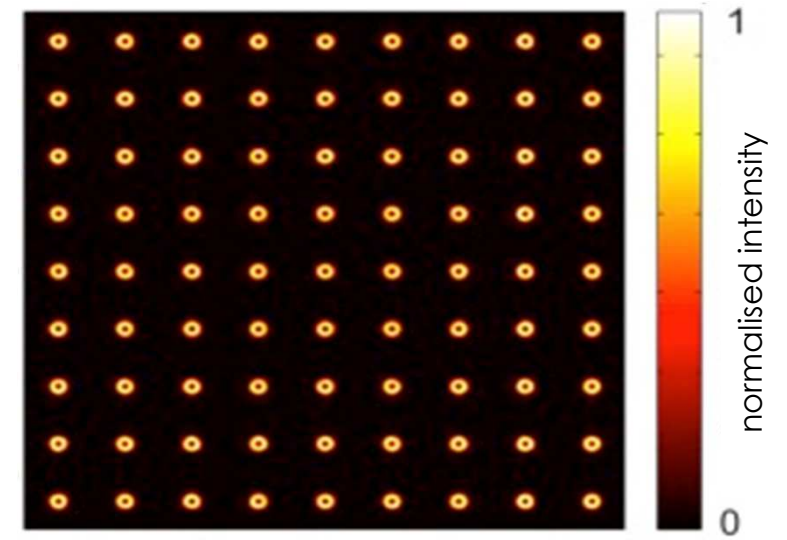
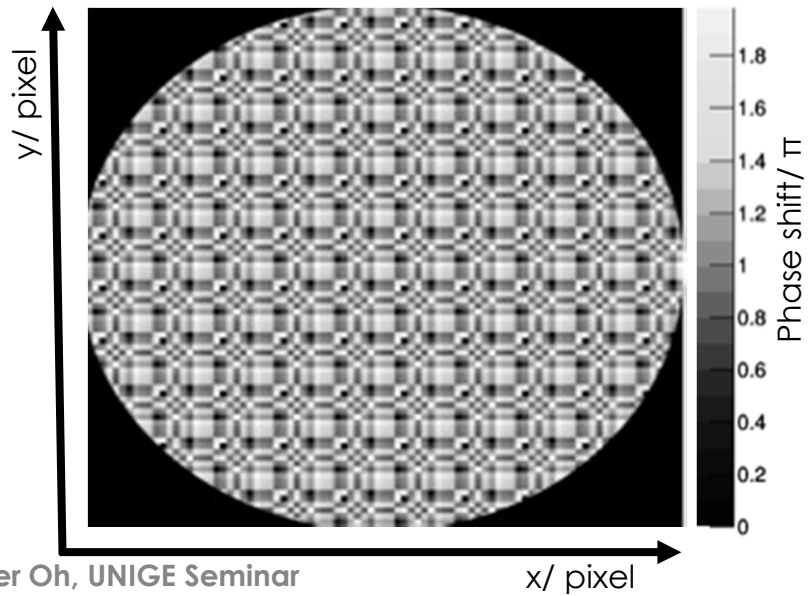
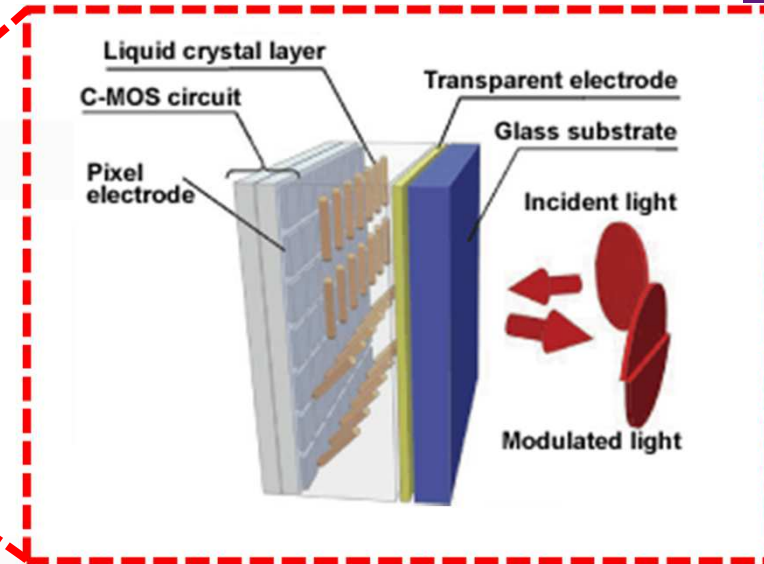
- Multiple passes reduces resistance and increases uniformity of the columns.

Multiple passes



- Multiple passes also reduces U_{ϕ} .

SLM parallel processing?

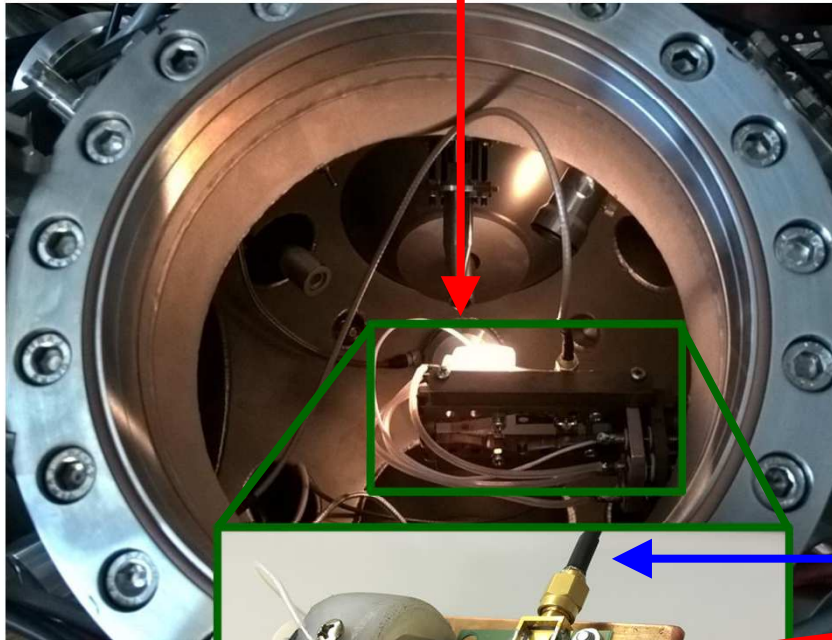
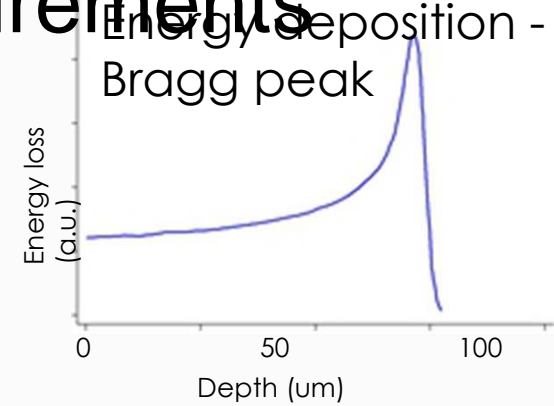


3D Detector Characterization

- Proton Micro-beam: 4.5 MeV p

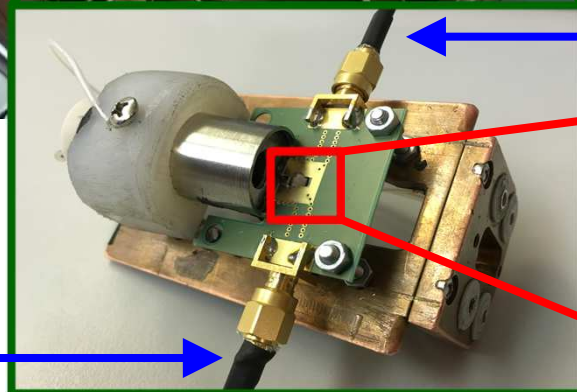
Proton micro-beam measurements

4.5 MeV
protons

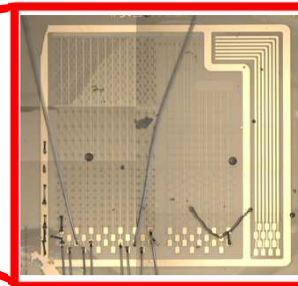


- Single particle beam.
- Rate ~ 1kHz.
- Beam position resolution < 2μm.

Read-out
channel 1



Read-out
channel 2

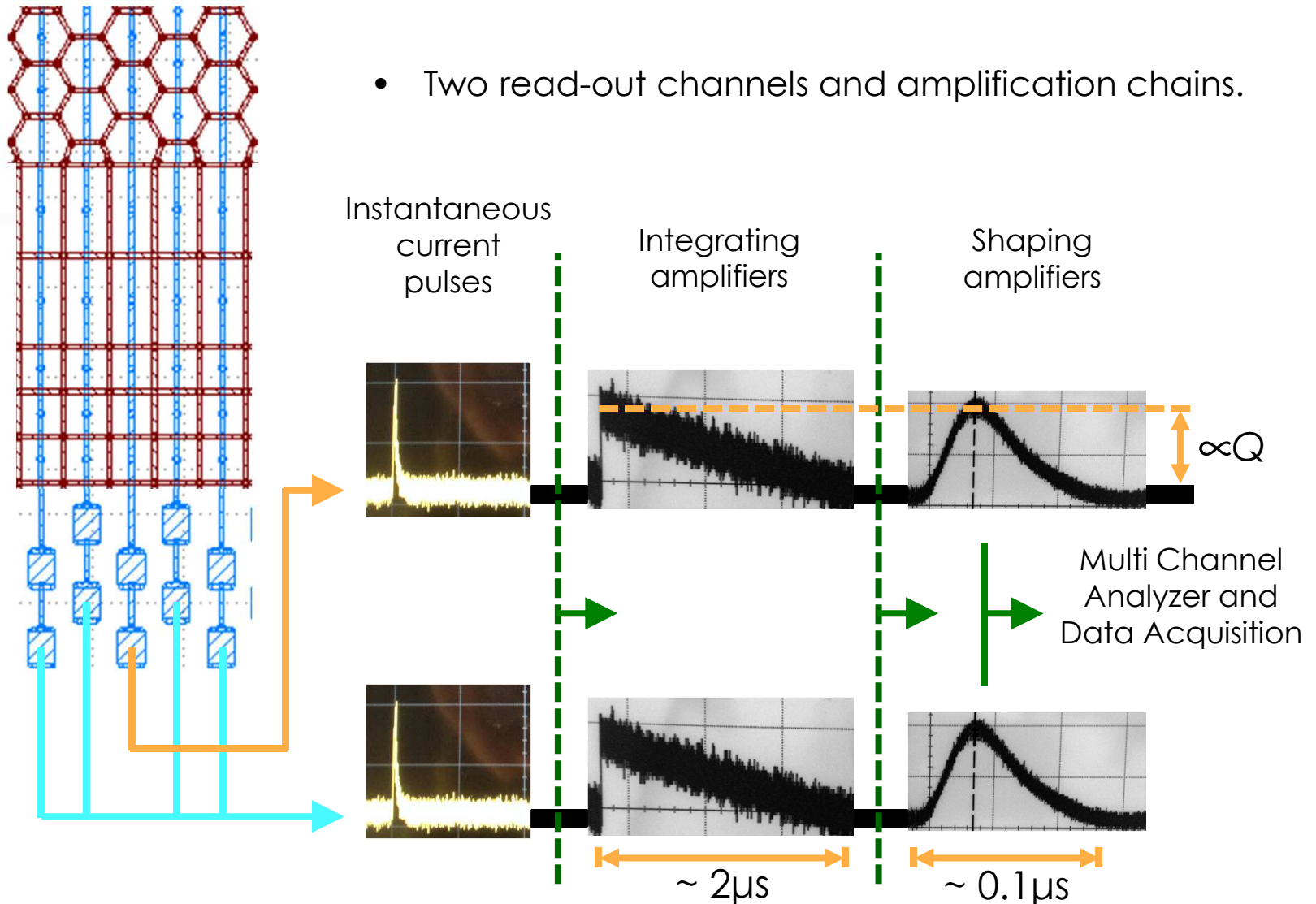


3D diamond
detector

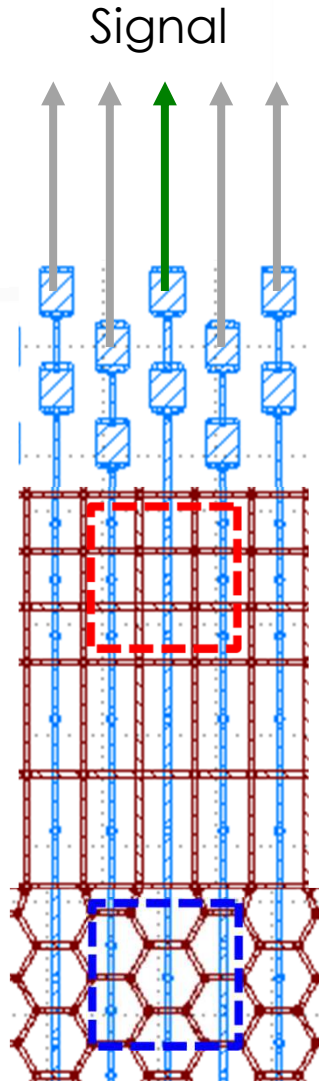
(TR)IBIC

(Time Resolved) Ion Beam Induced Current

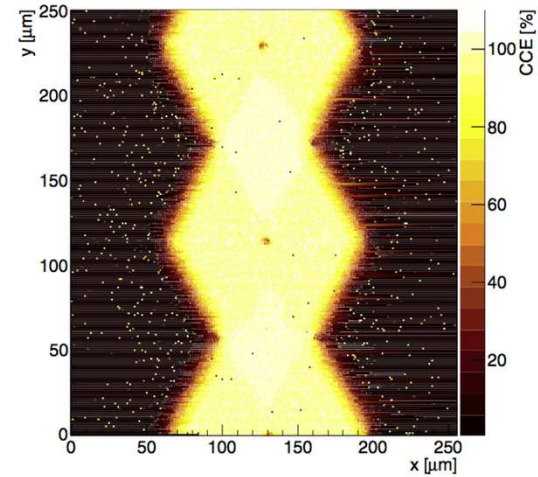
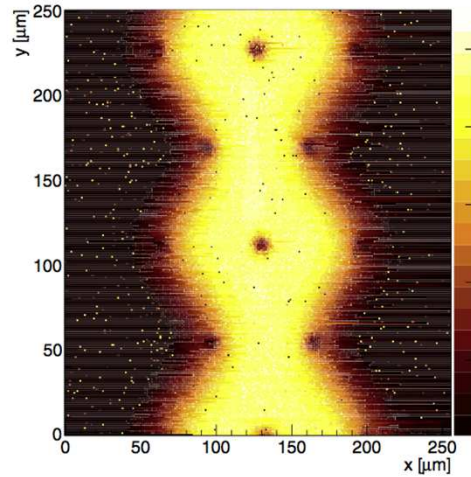
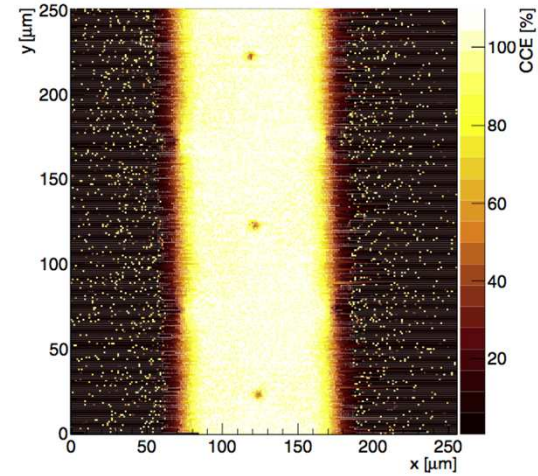
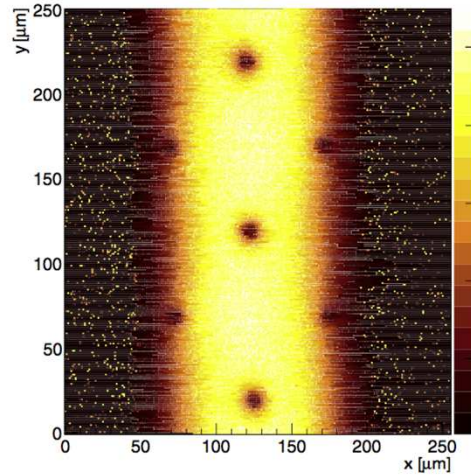
- Two read-out channels and amplification chains.



Signal efficiency at -2V and -20V

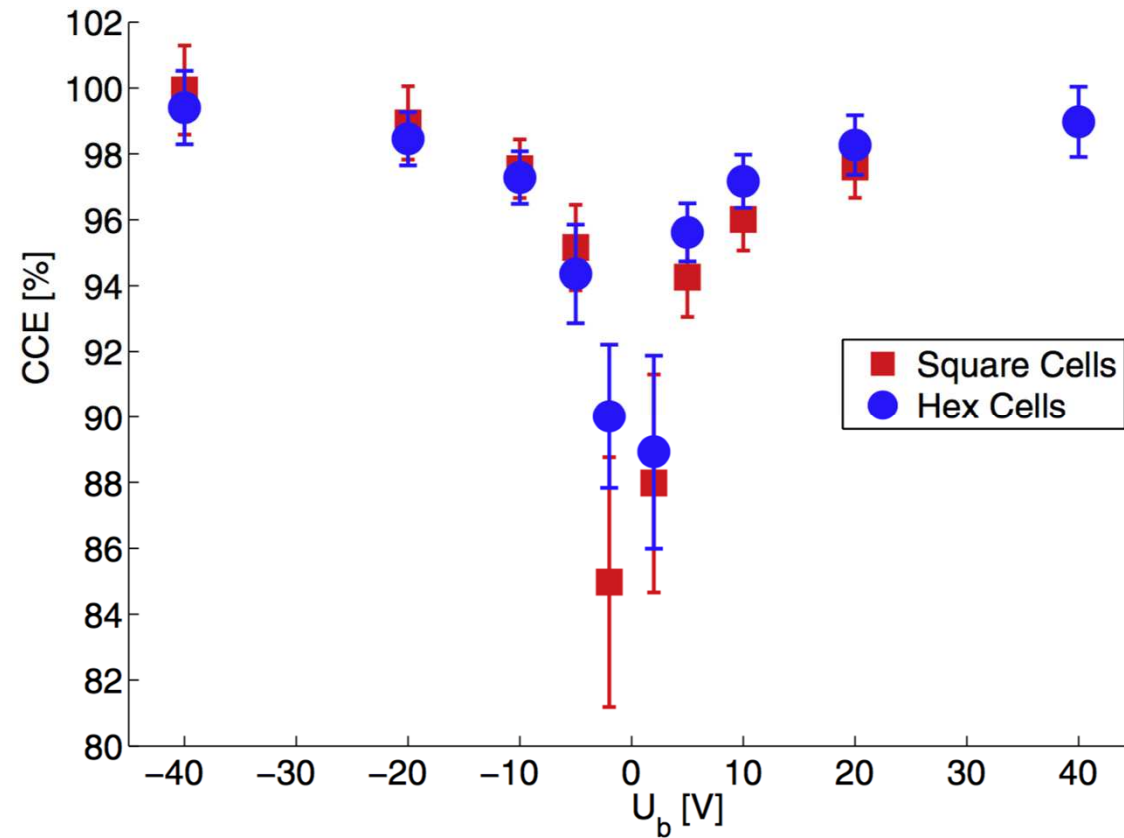
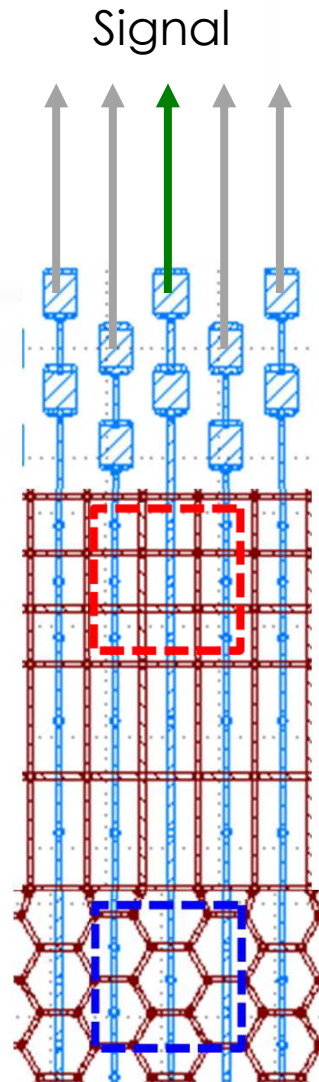


Square



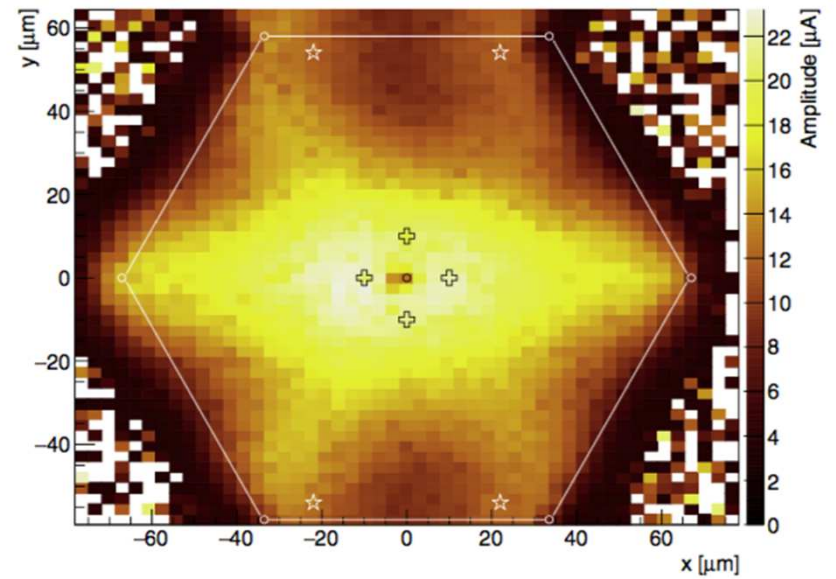
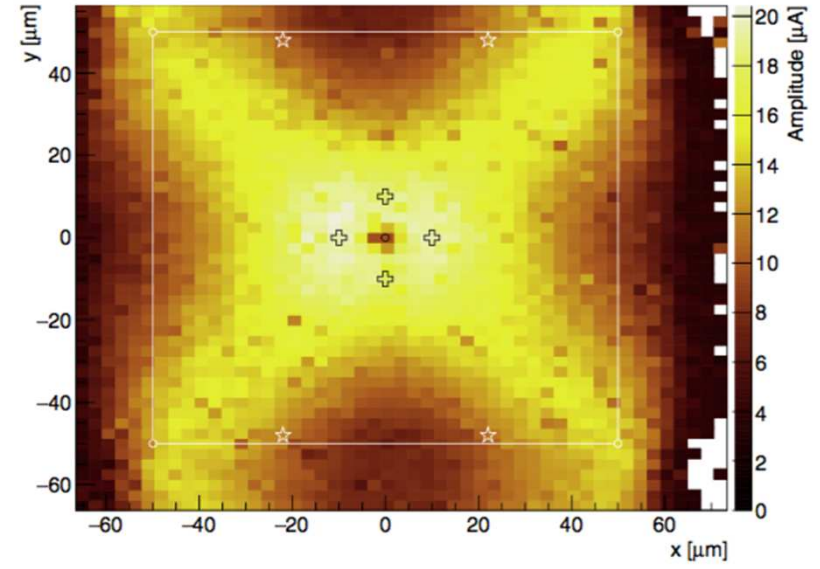
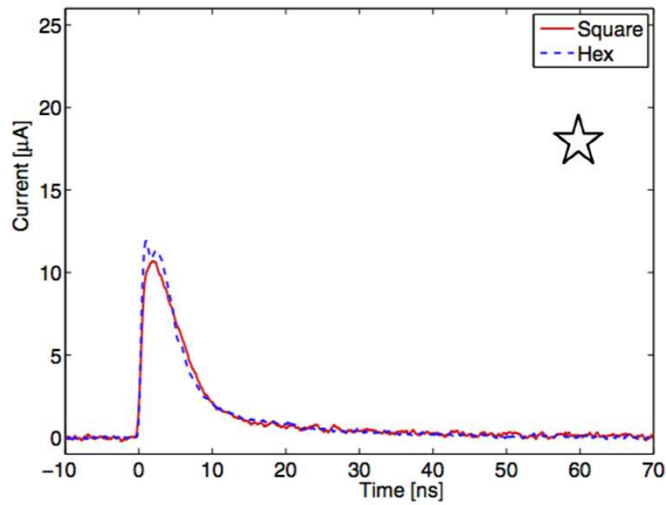
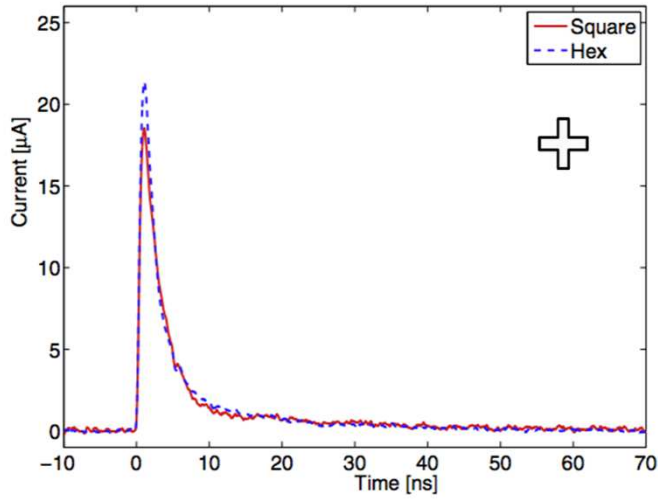
Hexagonal

Signal efficiency at -2V and -20V

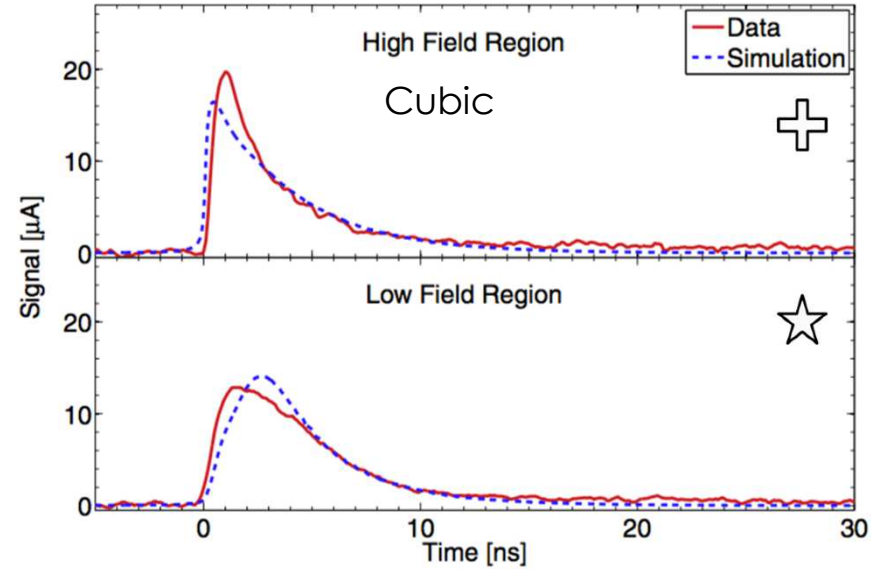
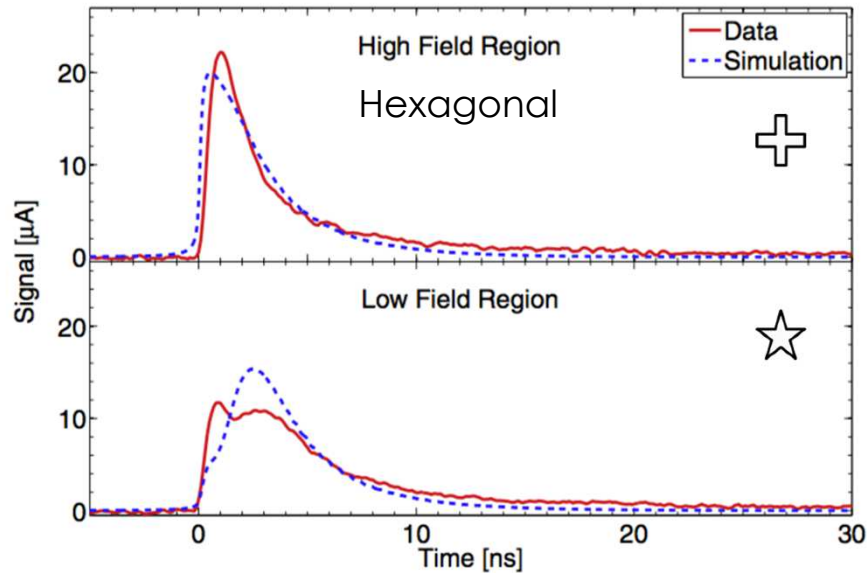


TRIBIC

$U_b = -20V$



TRIBIC: Results



Comparison with TCAD Simulation model:

- basic features qualitatively reproduced.
- Reasonable agreement, but simplified model.

3D Diamond detector tests with relativistic charged particles

- Types
 - 100x100um cell size ganged to form strips
 - 100x100um cell size, bonded to pixel read-out
 - 50x50um cell size, bonded to pixel read-out
- All detectors made from polycrystalline diamond.
- Beam tests
 - CERN beam line H6 : protons ~ 120 GeV/c
 - PSI : pions ~ 250 MeV/c

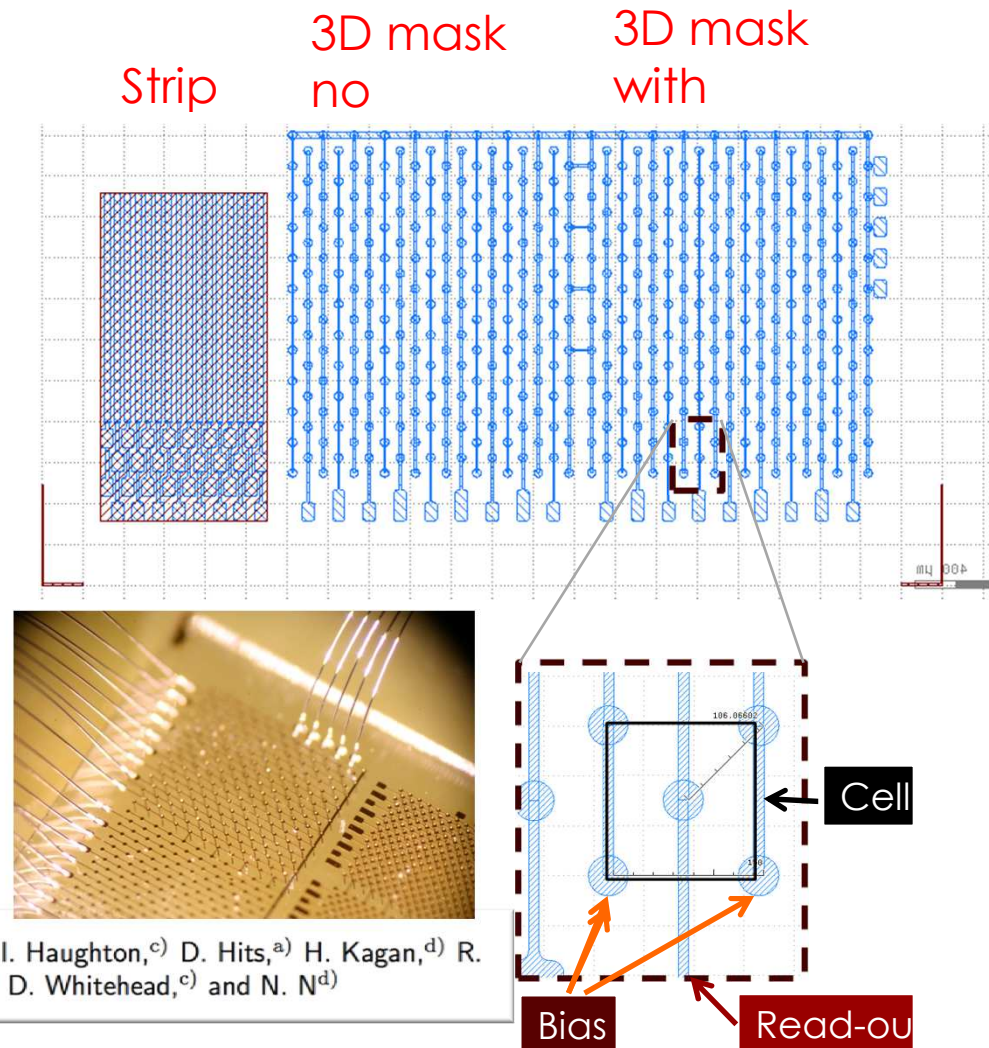
Thanks for material from the RD42 collaboration!

3D Diamond prototype

■ Proto-type

- Strip detector with back side contact
- 3D metal only pattern
- 3D metal + graphitic columns
- Cubic cell base size $150\mu\text{m}$
- 99 cells
- Measure response with 120 GeV protons.
- Paper published NIMA "A 3D diamond detector for particle tracking", NIM A, 786 (2015)

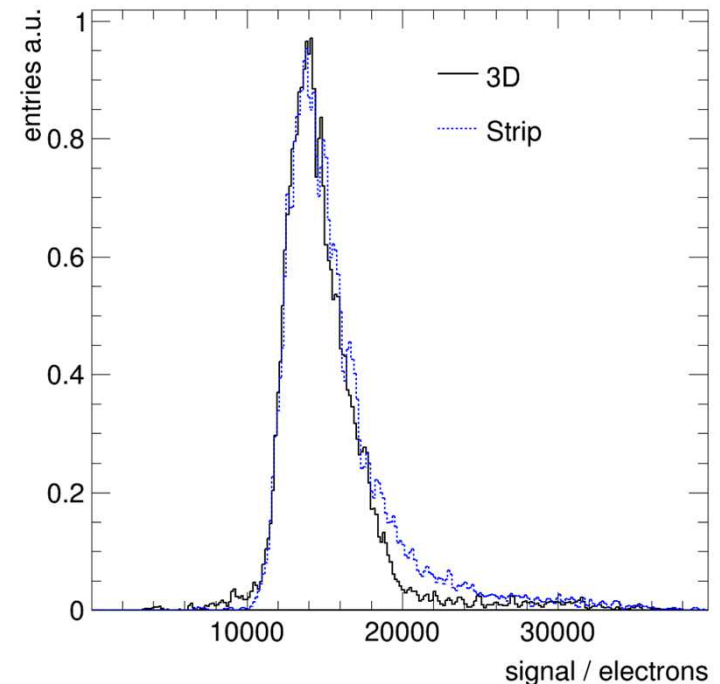
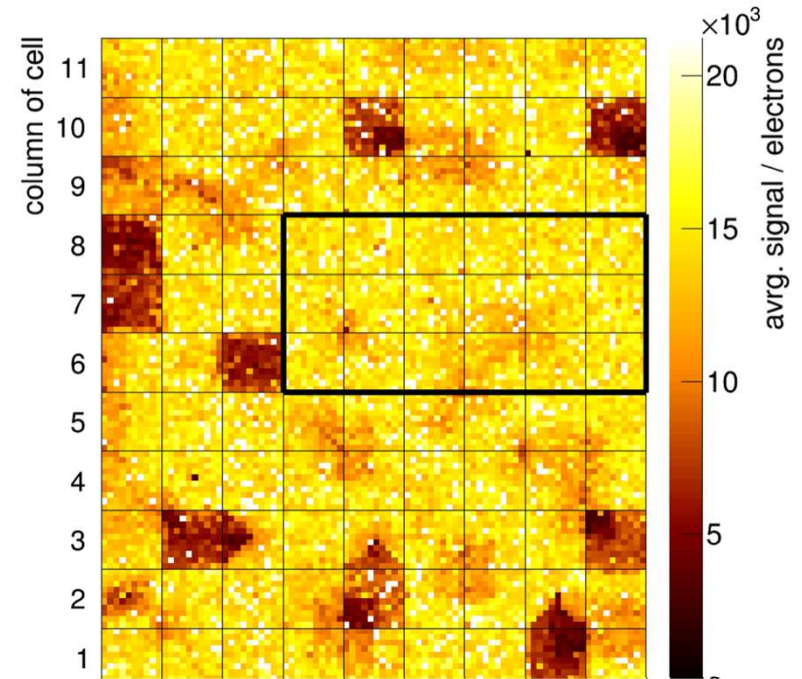
F. Bachmair,^{a)} L. Baeni,^{a)} P. Bergonzo,^{b)} B. Caylar,^{b)} G. Forcolin,^{c)} I. Haughton,^{c)} D. Hits,^{a)} H. Kagan,^{d)} R. Kass,^{d)} L. Li,^{c)} A. Oh,^{c)} M. Pomorski,^{b)} V. Tyzhnevyy,^{c)} R. Wallny,^{a)} D. Whitehead,^{c)} and N. N^{d)}



Analysis steps

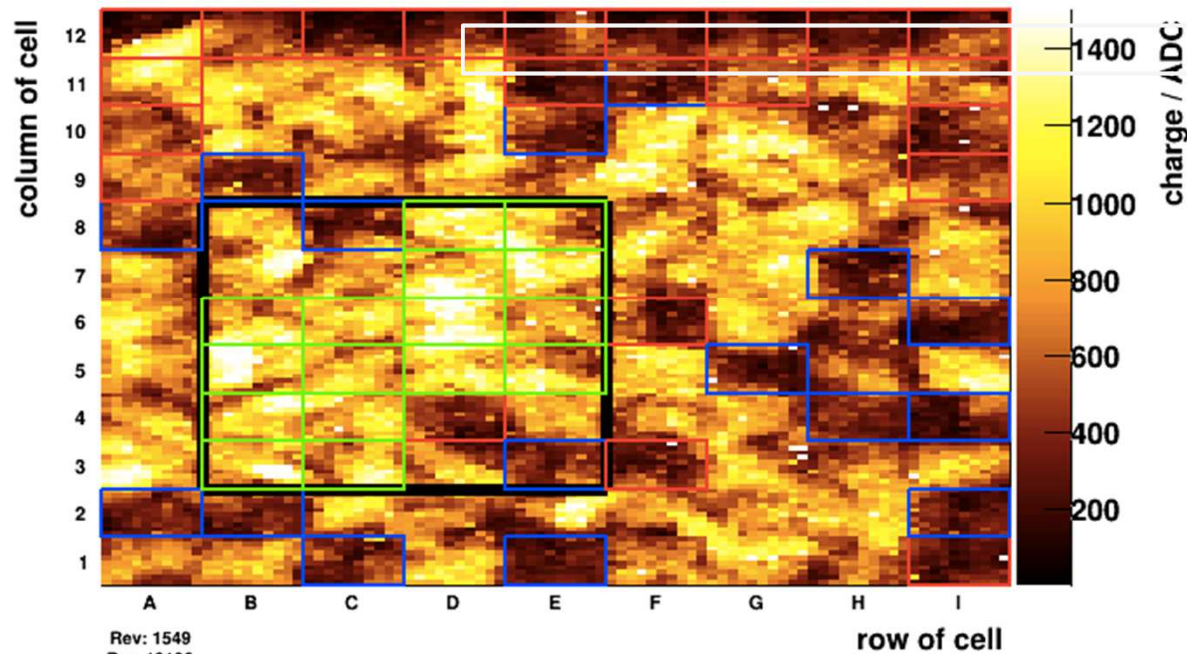
- $U_b(3D)=40V$
- $U_b(\text{strip})=500V$
- Identify **continuous region** of intact cells for analysis.
- Exclude contribution of negative signals.
- **Average charge**
Strip: 16.8ke
3D: 15.9ke
- **MP:**
Strip: 14.7ke
3D: 15ke

3D and Strip show comparable response.
Conclusion -> 3D works!



Test of first 3D **pCVD** diamond detectors

hPulseHeightVsDetectorHitPositionXY_trans

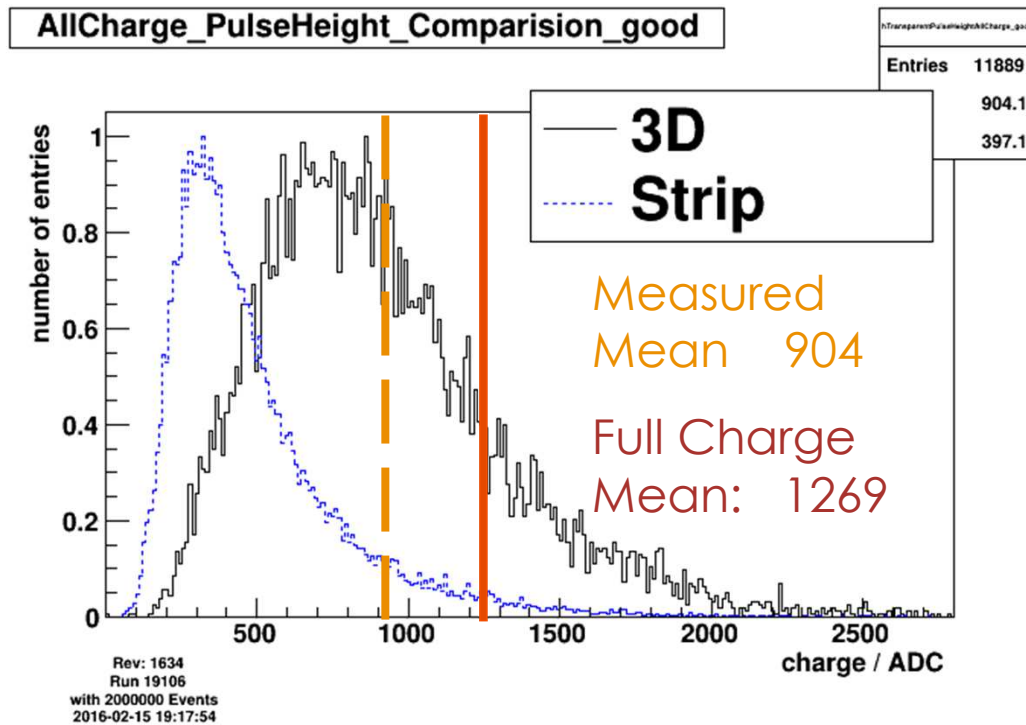


Rev: 1549
Run 19106
with 2000000 Events
2016-02-02 13:34:21

- $U_b(3D)=75V$
- $U_b(strip)=500V$
- Selected 16 adjacent cells

Test of first 3D **pCVD** diamond detectors

- Red line estimate the Mean for Full Charge Collection (100%)



71% of Full Charge Collection, corresponding to ~13 ke.

Highest charge collection ever measured for pCVD diamonds

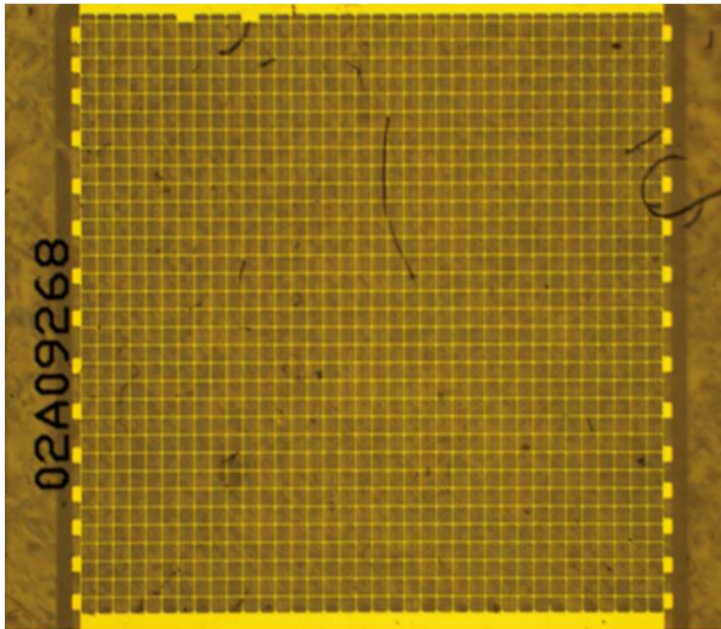
Large area 3D, pCVD, 100x100

58

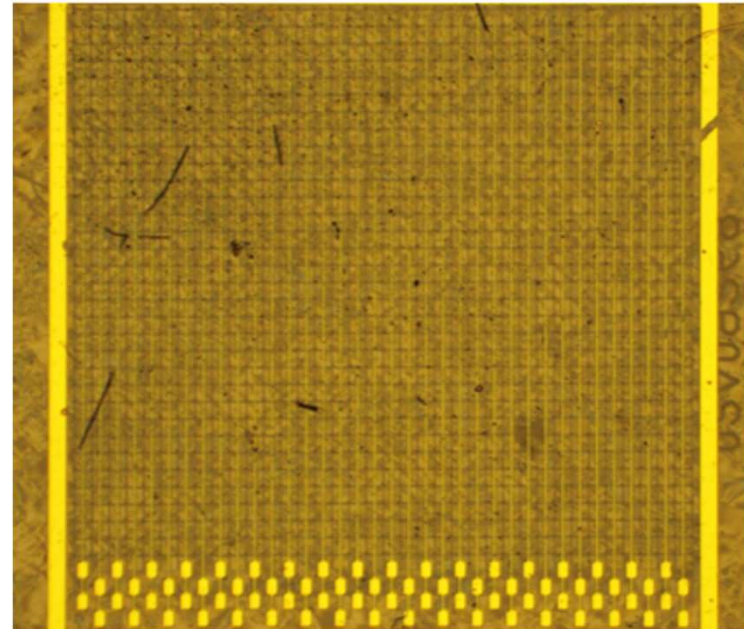
In May/Sept 2016 tested the first full 3D device fabricated in pcCVD with three dramatic improvements:

1. An order of magnitude more cells (1188 vs 99).
2. Smaller cell size (100um vs 150um).
3. Higher column production efficiency (>99% vs ~90%).

HV side



Readout side



Large area 3D, pCVD, 100x100

59

In May/Sept 2016 tested the first full 3D device fabricated in pcCVD with three dramatic improvements:

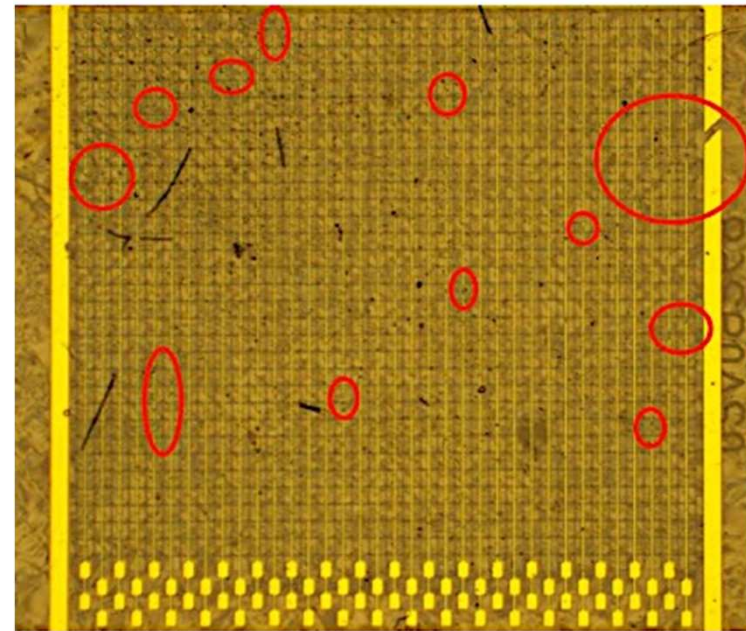
1. An order of magnitude more cells (1188 vs 99).
2. Smaller cell size (100um vs 150um).
3. Higher column production efficiency (>99% vs ~90%).

Some issues with handling procedures led to:

- Surface contamination.
- Some breaks in surface metallisation.

→ All fixable!

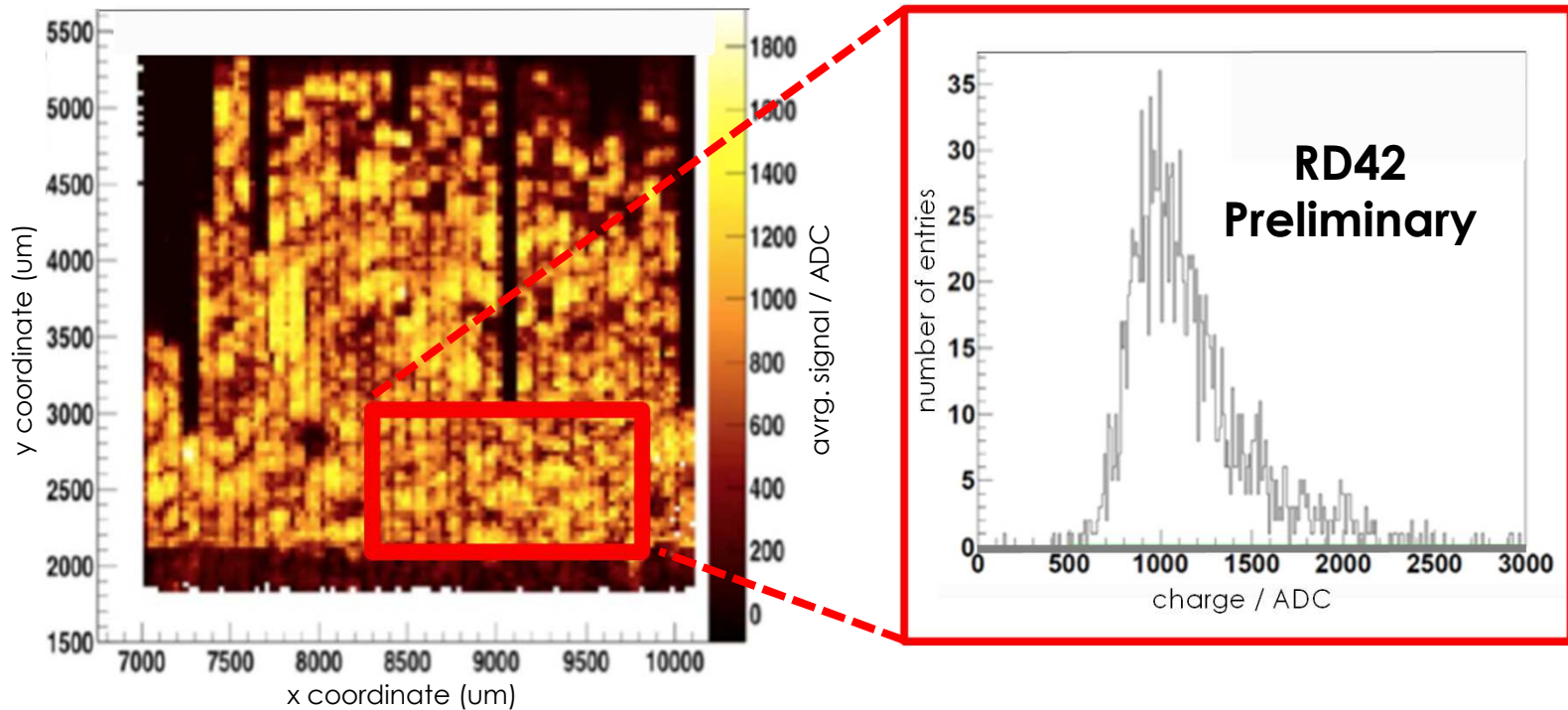
Readout side



Large area 3D, pCVD, 100x100

60

- Largest charge collection to date in pcCVD diamond!
 - >85 % of charge collected in continuous region.
- Analysis in progress on full detector.

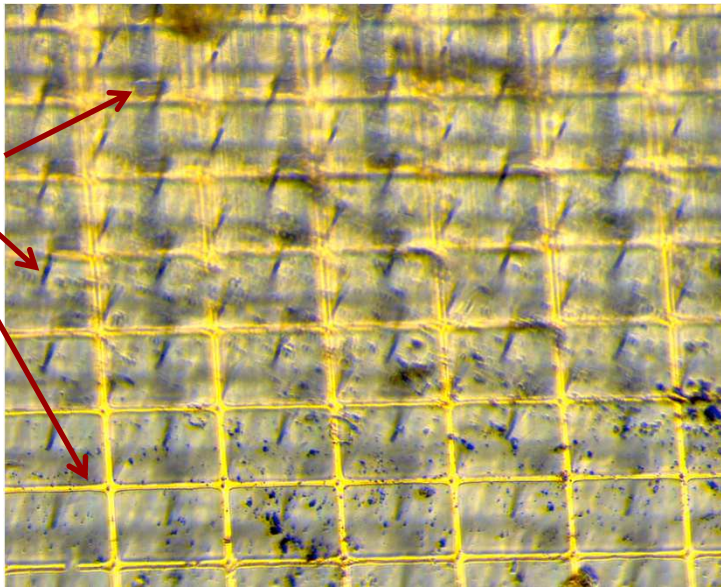


Pixel 3D, pCVD, 100x100

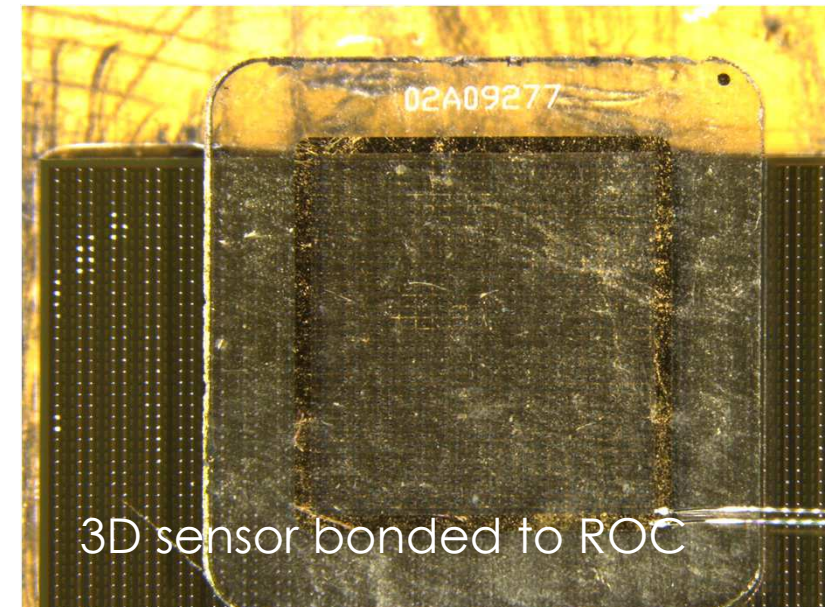
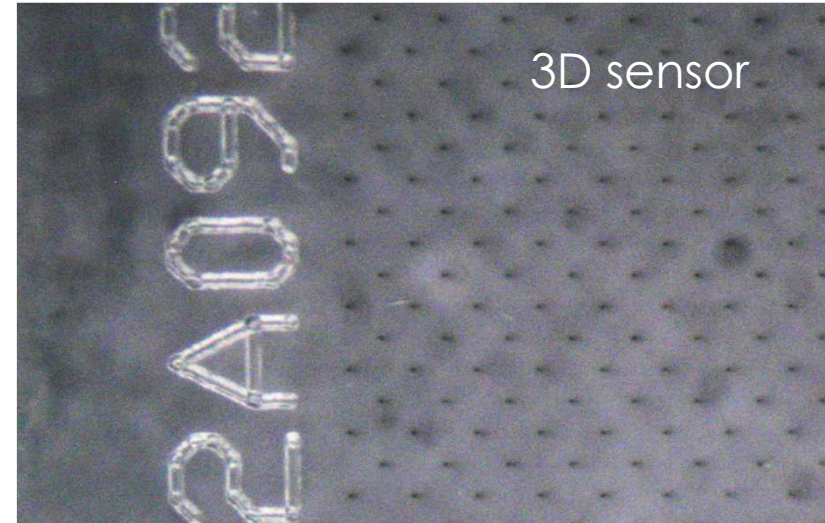
61

- First assembly with ROC chip produced.
 - Bump bonded in Princeton.
 - Cr-Au on bias side.
 - Ti-W under-bump metal.
 - Indium bumps on sensor.

Bump pads
Columns
Bias grid



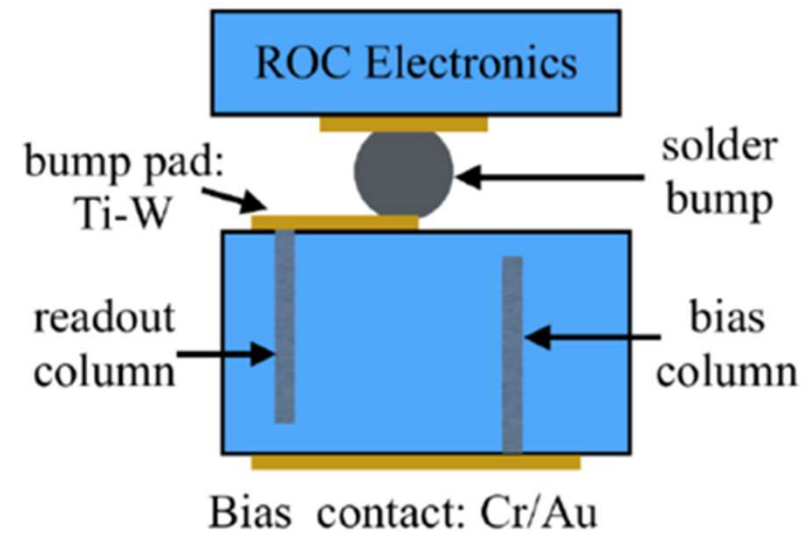
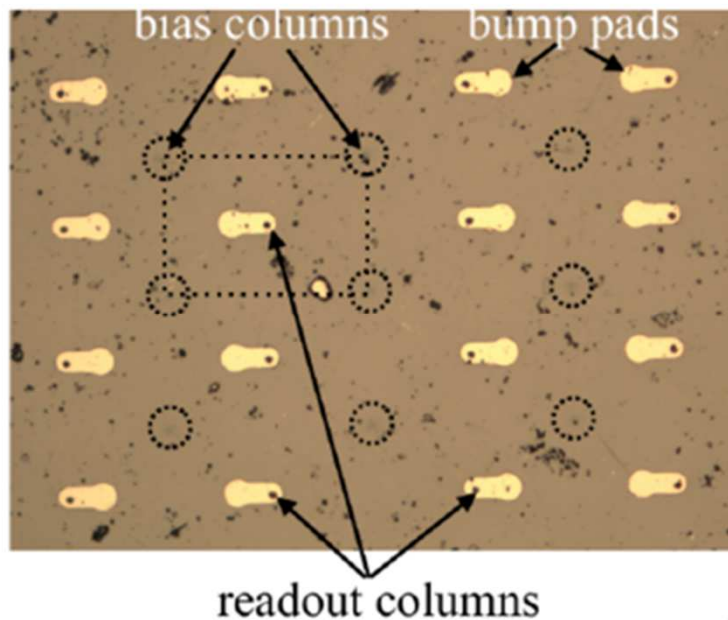
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Pixel 3D, pCVD, 100x100

62

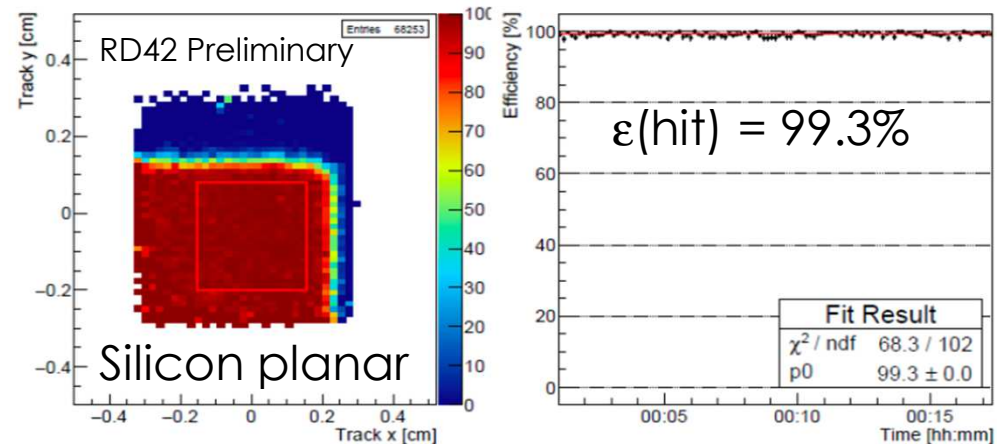
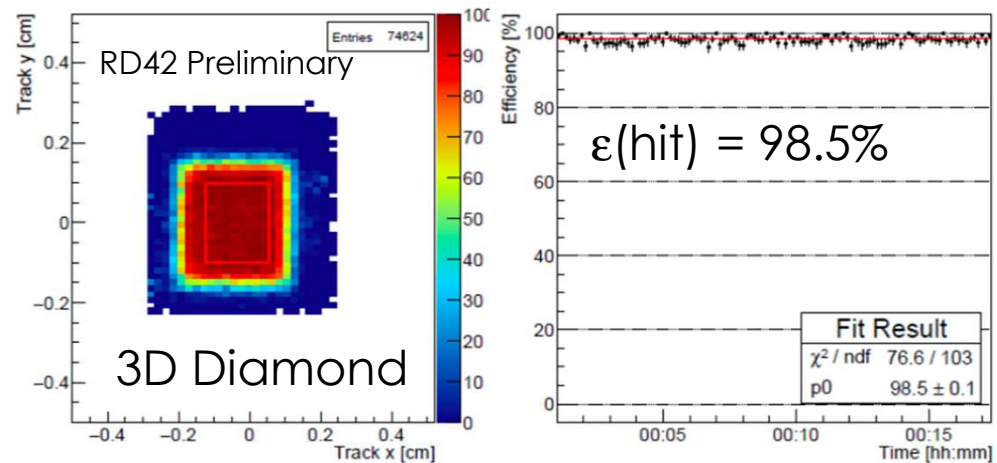
- Production of first pixel device using CMS readout electronics.



- Active region 3x3 mm with cell size $\sim 100 \times 100$ μm .

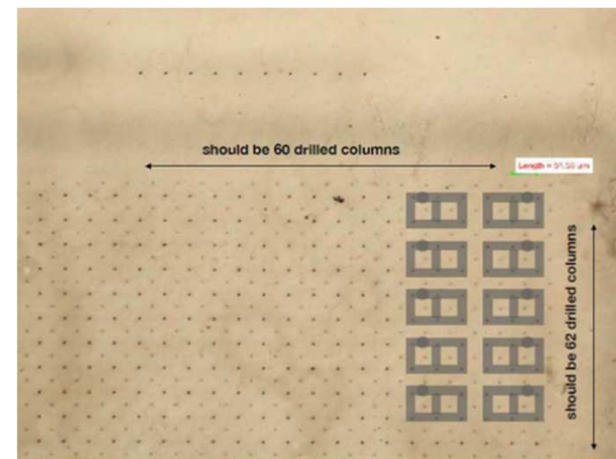
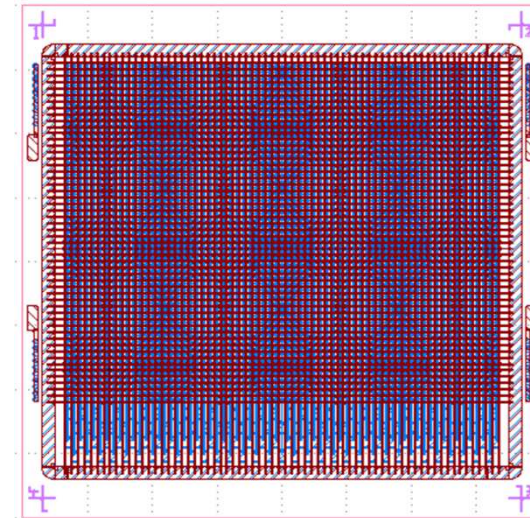
Pixel 3D, pCVD, 100x100

- Tested at PSI testbeam.
 - 3D diamond device and Silicon reference planar device.
 - Pixel threshold 1500e.
 - Check hit efficiency over time.
 - Device works!



Next generation 3D Diamond

- Produced 3500 Cell pixel prototype, 50x50um cell size.
- Sample production:
 - Oxford (2x cubic cells)
 - Manchester set-up in progress (expected production date end of month.)
- Bump bonding
 - For ROC (CMS) Princeton.
 - For FE-I4 (ATLAS) IFAE.
- Data taking in August 2017 at PSI.
- This week in testbeam at CERN

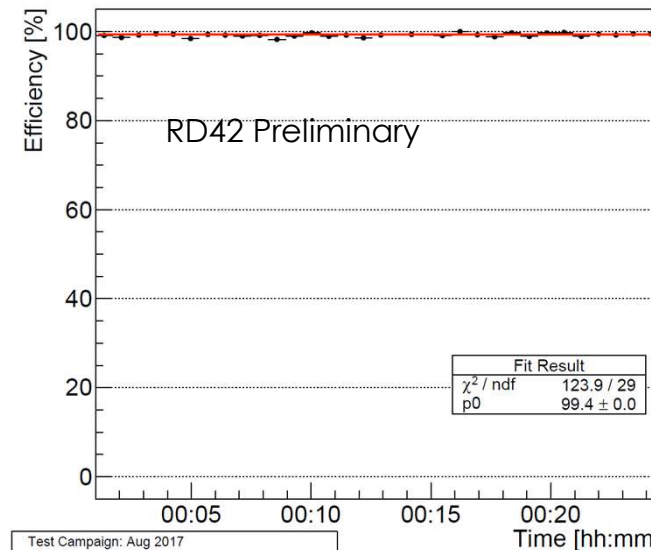
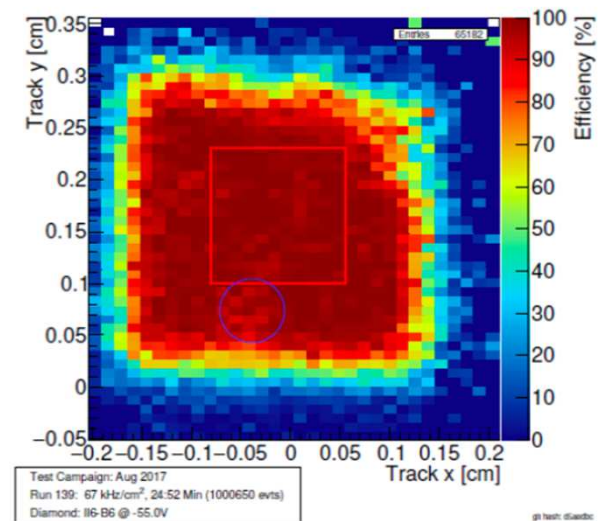


50x50 μm cell 3D Diamond

RD42 Preliminary

Preliminary Results (50 μm x50 μm pixels)

- Readout with CMS pixel readout.
- Bump bonding issue in upper right edge (Indium bump deposition machine not working properly)
- 6 columns (3x2) ganged together.
- Preliminary hit efficiency **99.2%**
- Preliminary: Collect **>90%** of charge!
- Rate dependence tested with 10 kHz/cm² and 10 MHz/cm² -> no dependence observed.



Summary

- Diamond systems are used as beam and luminosity monitors in current HEP experiments.
- Radiation hardness and rate dependence has been studied.
- 3D diamond has been demonstrated to work.
- The understanding of diamond as a detector material is advancing.

BACKUP

3D Diamond detector for medical dosimetry

Dosimetry application

- Planning of dose distribution delivered dose distribution challenging with narrow field beams.
- Need high spatial resolution of tissue equivalent dose deposited.
- Target numbers:
 - Dose uncertainty $<1\%$
 - Spatial resolution $\sim 0.1\text{mm}$



Dosimetry application

■ Diamond key properties for dosimetry

- Tissue equivalence
- Radiation hardness
- Room temperature operation
- bio-compatibility

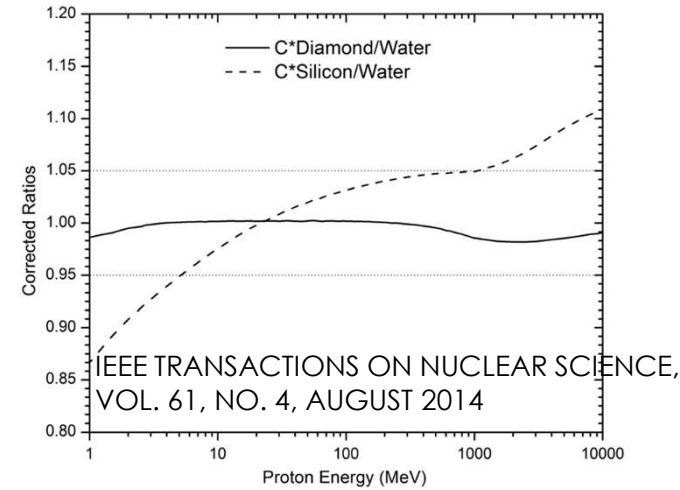
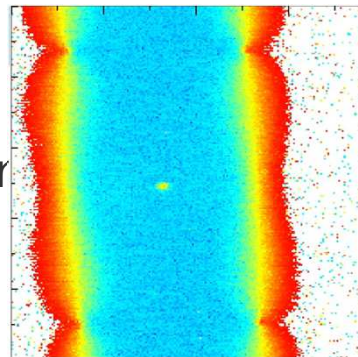


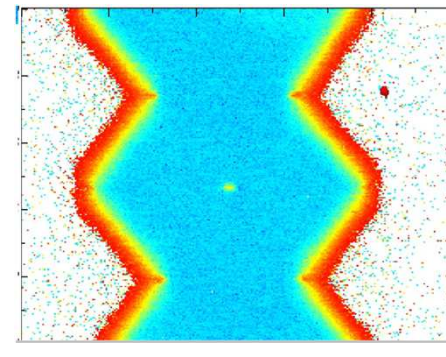
Fig. 14. Comparison of the corrected ratio of stopping powers for protons of diamond and silicon with water.

■ 3D Advantage

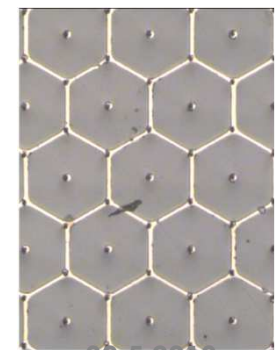
- Flexible active volume
- Radiation hardness
- Potential for 3D position information



100 μm



100 μm



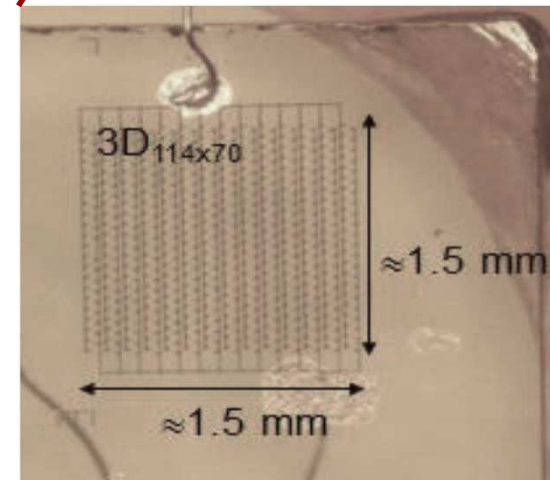
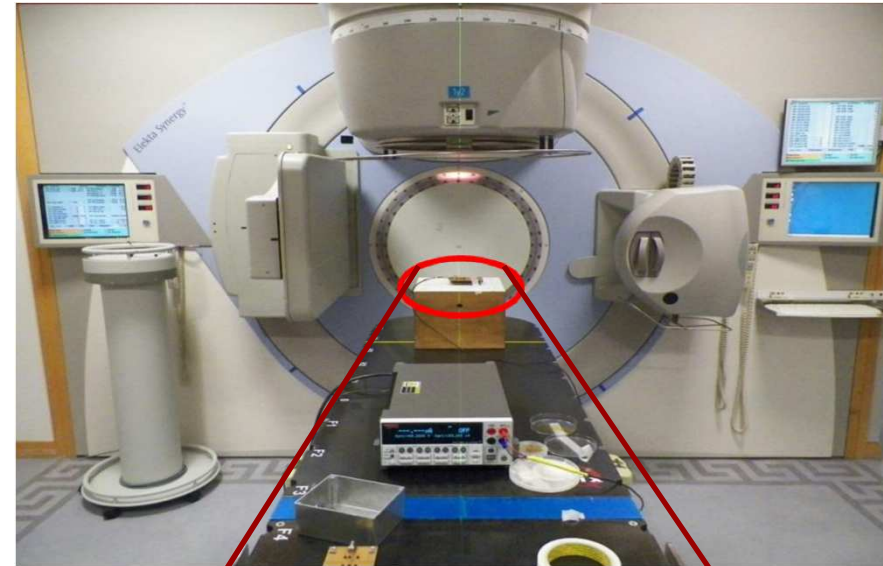
30.5.2018

Dosimetry application



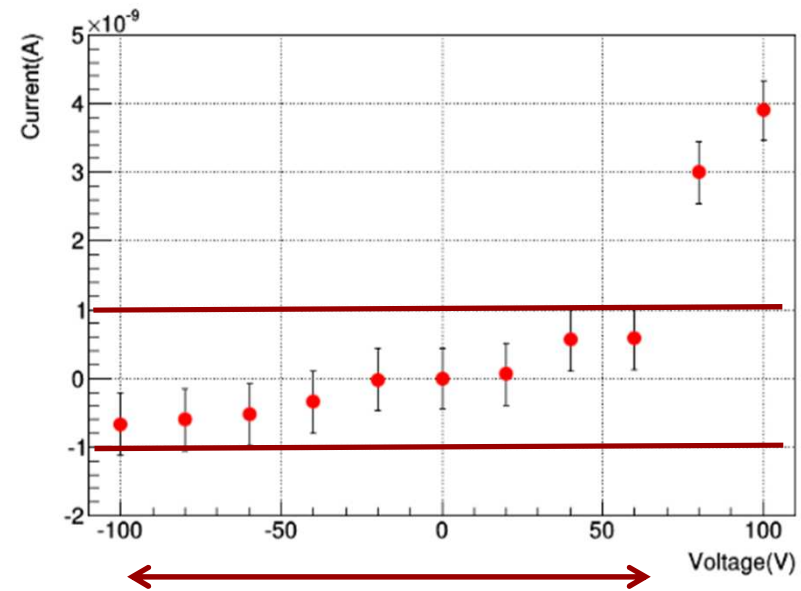
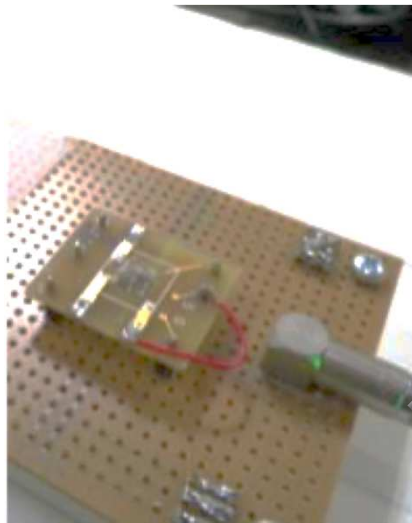
■ The Christie Hospital, Manchester

- medical linear accelerator (Elekta Synergy Sband)
- 6MV and 10MV acceleration.
- 10x10cm radiation field.
- Dose rate dependence.
- Photon beam profile.



Dosimetry application

- Test set-up:

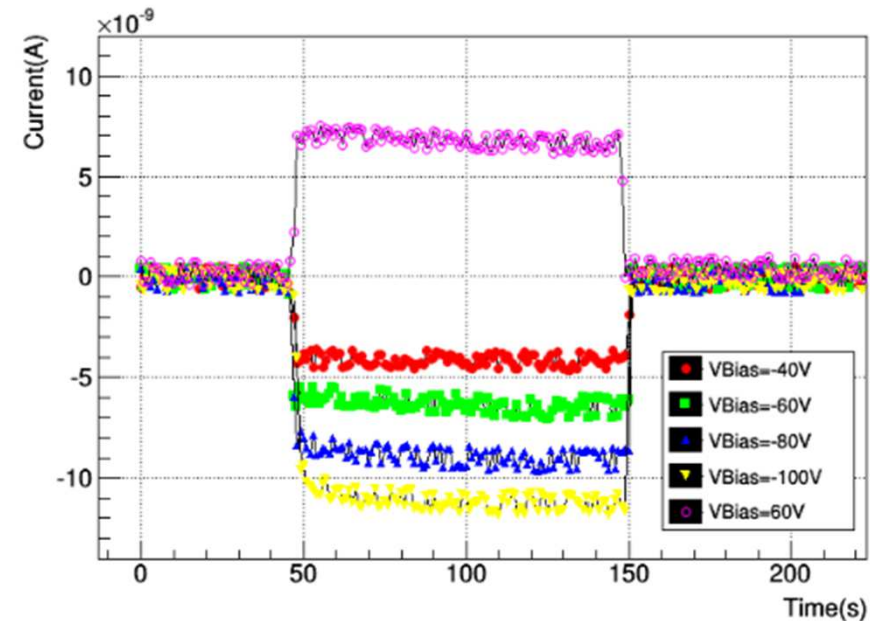


Asymmetric leakage current.
 $I_{\text{leak}} < 1 \text{ nA}$ for -100 V to $+60 \text{ V}$

Dosimetry application

First 3D diamond results:

- Pre-irradiated with 5 Gy.
- Clear response to presence to 6MV photons.
- Return to baseline <1s, no significant baseline shift.
- Plateau stability needs further studies.

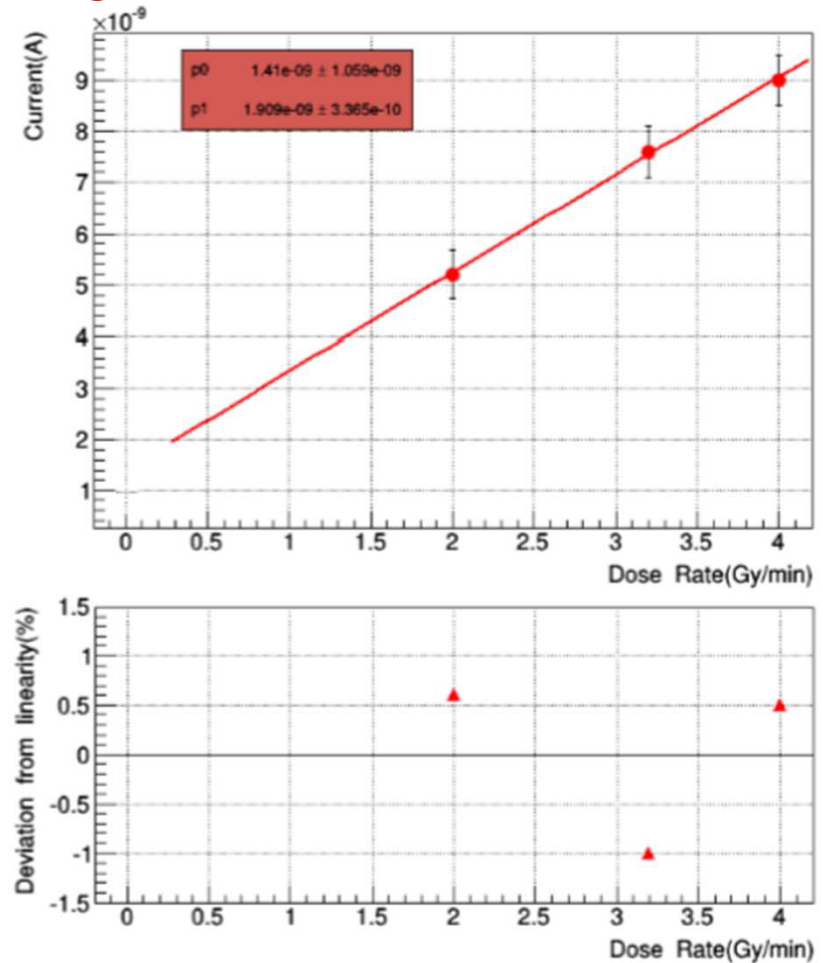


On-off response to 6MV photon beam with 4Gy/min.
Variation of bias voltage.

Dosimetry application

First 3D diamond results:

- Good linearity of $\sim 1\%$ over **dose rate** range of 2-4 Gy/min.

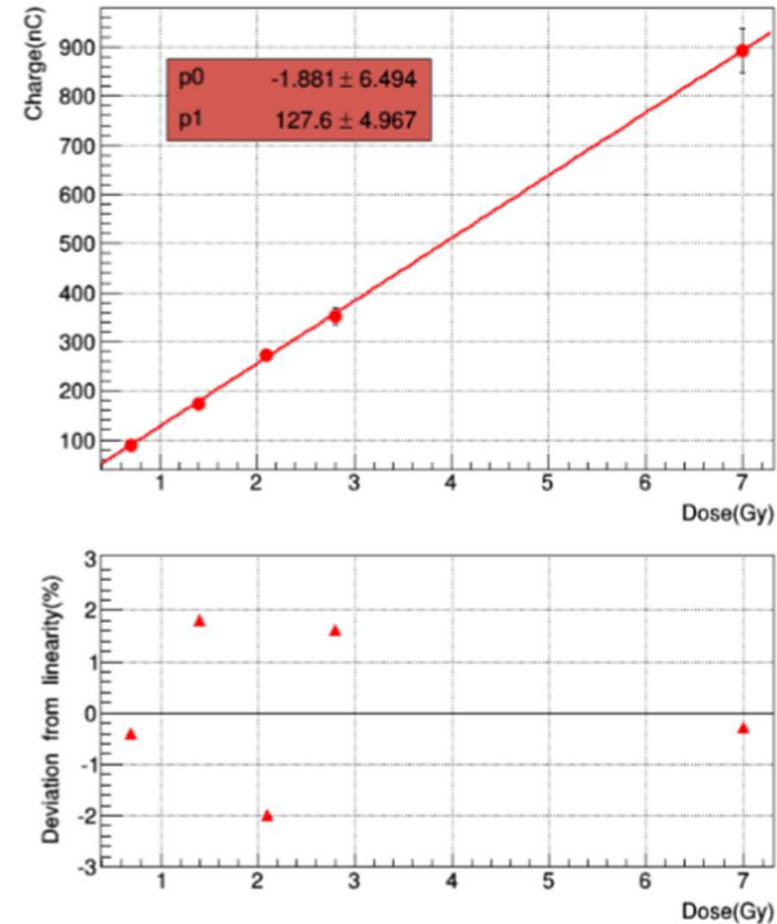


Dose rate linearity for 6MV photons at -80V

Dosimetry application

First 3D diamond results:

- Good linearity of $\sim 1\%$ over dose rate range of 2-4 Gy/min.
- Good linearity of $\sim 2\%$ over **dose range** of 0.5 to 7 Gy.

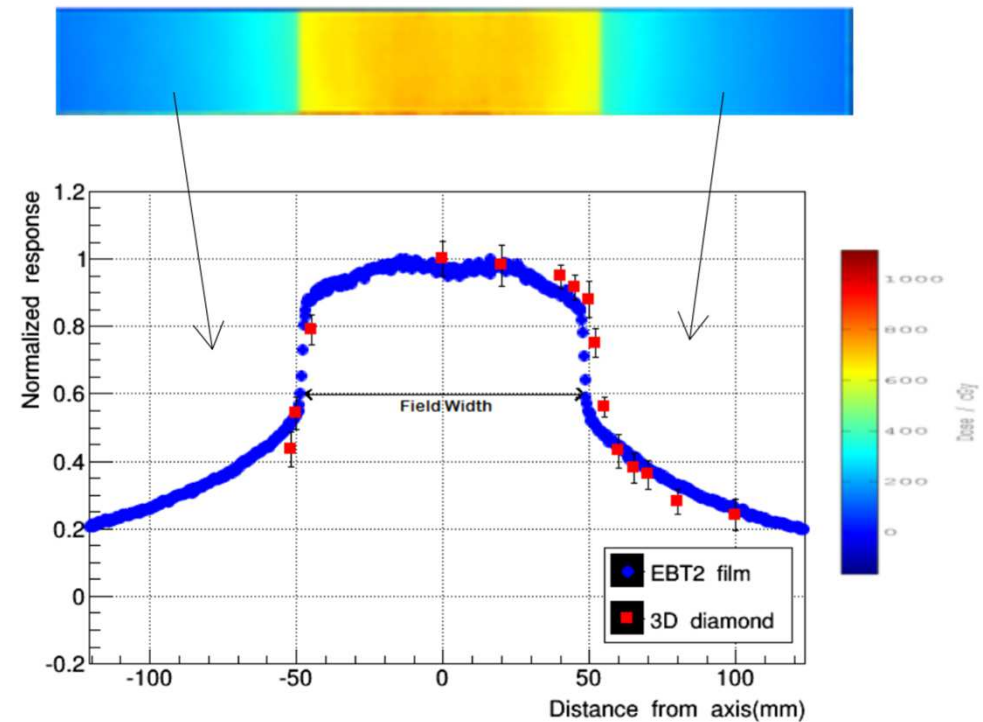


Dose linearity for 6MV photons at -80V

Dosimetry application

First 3D diamond results:

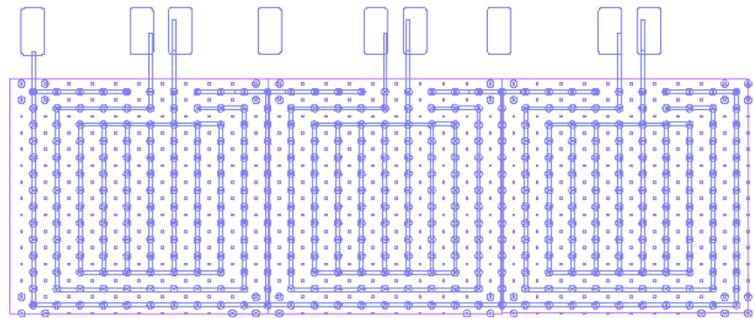
- Good linearity of $\sim 1\%$ over dose rate range of 2-4 Gy/min.
- Good linearity of $\sim 2\%$ over dose range of 0.5 to 7 Gy.
- **Beam width** well reproduced to 1% when compared to GafChromic film measurement.



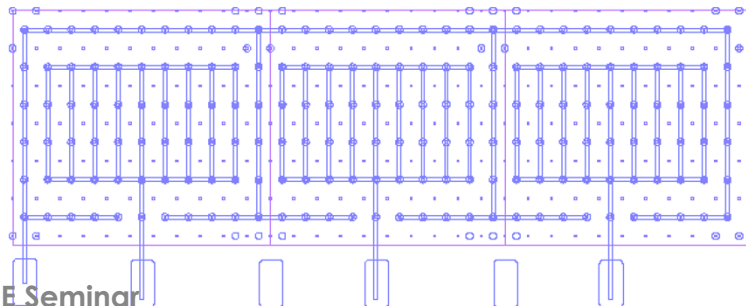
10cm beam profile measured with 3D diamond at -80V, 4Gy/min and film.

Next generation:

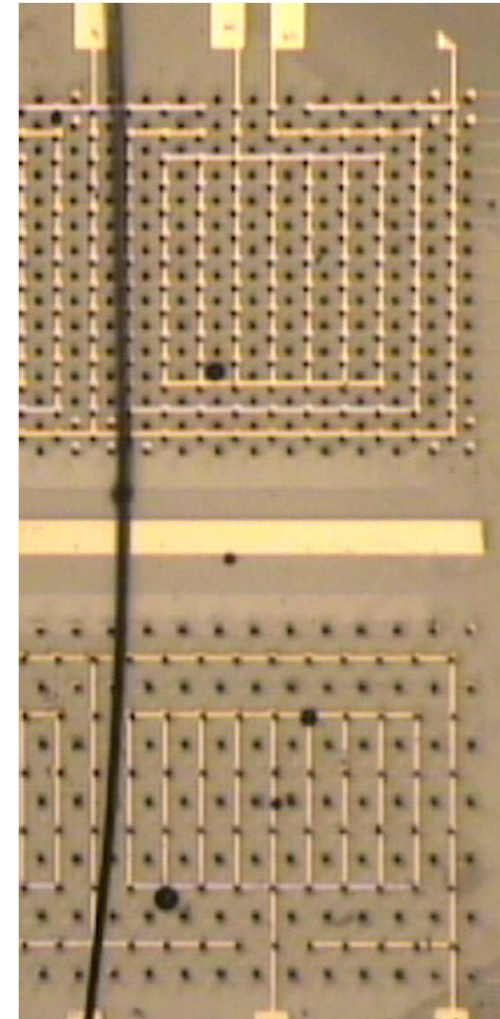
- Next generation tests with variable array sizes.



3166_0205



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30.5.2018